

Dual Channel 12-Bit 750 Msps Receiver and Feedback IC

Check for Samples: [ADS54T02](#)

FEATURES

- Dual Channel
- 12-Bit Resolution
- Maximum Clock Rate: 750 Msps
- Low Swing Fullscale Input: 1.0 Vpp
- Analog Input Buffer with High Impedance Input
- Input Bandwidth (3dB): >1.2GHz
- Data Output Interface: DDR LVDS
- 196-Pin BGA Package (12x12mm)
- Power Dissipation: 1050mW/ch
- Performance at $f_{in} = 230$ MHz IF
 - SNR: 60.7 dBFS
 - SFDR: 78 dBc

- Performance at $f_{in} = 700$ MHz IF
 - SNR: 58.9 dBFS
 - SFDR: 73 dBc
- Receive Mode: 2x Decimation with Low Pass or High Pass Filter
- Feedback Mode: Burst Mode Output for Full Bandwidth DPD Feedback

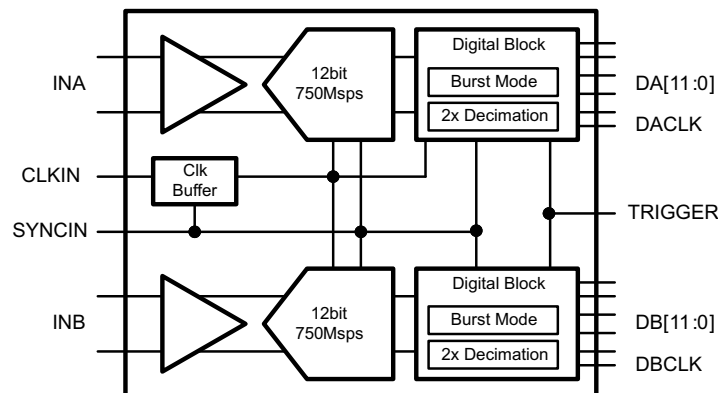
APPLICATIONS

- Telecommunications Receiver
- Power Amplifier Linearization

| Device Part No. | Number of Channels | Speed Grade |
|-----------------|--------------------|-------------|
| ADS54T02 | 2 | 750 Msps |
| ADS54T01 | 1 | 750 Msps |
| ADS54T04 | 2 | 500 Msps |

DESCRIPTION

The ADS54T02 is a high linearity dual channel 12-bit, 750 MSPS analog-to-digital converter (ADC) easing front end filter design for wide bandwidth receivers. The analog input buffer isolates the internal switching of the on-chip track-and-hold from disturbing the signal source as well as providing a high-impedance input. Two output modes are available for the output data – it can be decimated by two or the data can be output in burst mode. The burst mode output is designed specifically for DPD feedback applications where high resolution output data is available for a short period of time. Designed for high SFDR, the ADC has low-noise performance and outstanding spurious-free dynamic range over a large input-frequency range. The device is available in a 196pin BGA package and is specified over the full industrial temperature range (–40°C to 85°C).



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

DETAILED BLOCK DIAGRAM

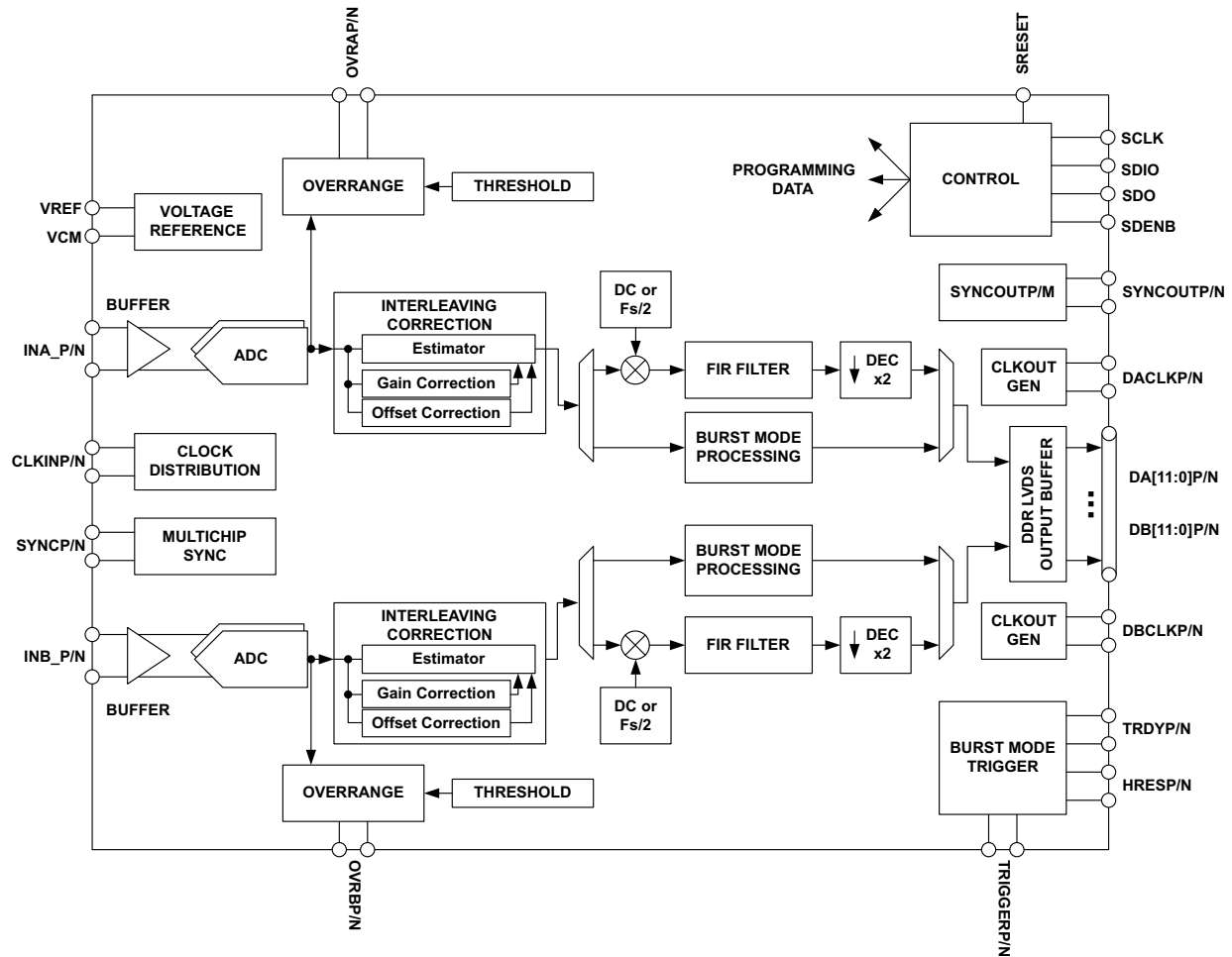


Figure 1. Detailed Block Diagram

PINOUT INFORMATION

| | A | B | C | D | E | F | G | H | J | K | L | M | N | P | |
|----|-------|-----------|-----------|-----------|--------|-----------|--------|--------|--------|--------|-----------|-----------|-----------|-----------|----|
| 14 | VREF | VCM | GND | INB_N | INB_P | GND | AVDDC | AVDDC | GND | INA_P | INA_N | GND | GND | CLKINP | 14 |
| 13 | SDENB | TEST MODE | GND | GND | GND | GND | GND | GND | GND | GND | GND | GND | GND | CLKINN | 13 |
| 12 | SCLK | SRESET | GND | AVDD33 | AVDD33 | AVDD33 | AVDD33 | AVDD33 | AVDD33 | AVDD33 | AVDD33 | GND | AVDD33 | AVDD33 | 12 |
| 11 | SDIO | ENABLE | GND | AVDD18 | AVDD18 | AVDD18 | AVDD18 | AVDD18 | AVDD18 | AVDD18 | AVDD18 | GND | AVDD18 | AVDD18 | 11 |
| 10 | SDO | IOVDD | GND | AVDD18 | GND | GND | GND | GND | GND | GND | AVDD18 | GND | TRIGGER N | TRIGGER P | 10 |
| 9 | DVDD | DVDD | GND | GND | GND | GND | GND | GND | GND | GND | GND | GND | SYNCN | SYNCP | 9 |
| 8 | DVDD | DVDD | DVDD | DVDD | GND | GND | GND | GND | GND | GND | DVDD | DVDD | DVDD | DVDD | 8 |
| 7 | DB0N | DB0P | DVDD LVDS | DVDD LVDS | GND | GND | GND | GND | GND | GND | DVDD LVDS | DVDD LVDS | TRDYN | TRDYP | 7 |
| 6 | DB1N | DB1P | DVDD LVDS | DVDD LVDS | GND | GND | GND | GND | GND | GND | DVDD LVDS | DVDD LVDS | HRESN | HRESP | 6 |
| 5 | DB2N | DB2P | OVRBN | OVRBP | GND | GND | GND | GND | GND | GND | OVRAN | OVRAP | SYNC OUTN | SYNC OUTP | 5 |
| 4 | DB3N | DB3P | DB8P | DB10P | NC | HRESP | TRDYP | DA0P | DA2P | DA4P | DA6P | DA8P | NC | NC | 4 |
| 3 | DB4N | DB4P | DB8N | DB10N | NC | HRESN | TRDYN | DA0N | DA2N | DA4N | DA6N | DA8N | DA11N | DA11P | 3 |
| 2 | DB5N | DB5P | DB7P | DB9P | DB11P | SYNC OUTP | DBCLKP | DACLKP | DA1P | DA3P | DA5P | DA7P | DA10N | DA10P | 2 |
| 1 | DB6N | DB6P | DB7N | DB9N | DB11N | SYNC OUTN | DBCLKN | DACLKN | DA1N | DA3N | DA5N | DA7N | DA9N | DA9P | 1 |
| | A | B | C | D | E | F | G | H | J | K | L | M | N | P | |

Figure 2. Pinout in DDR output mode (top down view)

PIN ASSIGNMENTS

| PIN | | I/O | DESCRIPTION |
|-----------------|----------|-----|--|
| NAME | NUMBER | | |
| INPUT/REFERENCE | | | |
| INA_P/N | K14, L14 | I | Analog ADC A differential input signal. |
| INB_P/N | D14, E14 | I | Analog ADC B differential input signal. |
| VCM | B14 | O | Output of the analog input common mode (nominally 1.9V). A 0.1μF capacitor to AGND is recommended. |
| VREF | A14 | O | Reference voltage output. A 0.1μF capacitor to AGND is recommended, but not required. |
| CLOCK/SYNC | | | |
| CLKINP/N | P14, P13 | I | Differential input clock |
| SYNCP/N | P9, N9 | I | Synchronization input. Inactive if logic low. When clocked in a high state initially, this is used for resetting internal clocks and digital logic and starting the SYNCOUT signal. Internal 100Ω termination. |
| CONTROL/SERIAL | | | |
| SRESET | B12 | I | Serial interface reset input. Active low. Initialized internal registers during high to low transition. Asynchronous. Internal 50kΩ pull up resistor to IOVDD. |

PIN ASSIGNMENTS (continued)

| PIN | | I/O | DESCRIPTION |
|-----------------------|--|-----|--|
| NAME | NUMBER | | |
| ENABLE | B11 | I | Chip enable – active high. Power down function can be controlled through SPI register assignment. Internal 50kΩ pull up resistor to IOVDD. |
| SCLK | A12 | I | Serial interface clock. Internal 50kΩ pull-down resistor. |
| SDIO | A11 | I/O | Bi-directional serial data in 3 pin mode (default). In 4-pin interface mode (register x00, D16), the SDIO pin in an input only. Internal 50kΩ pull-down. |
| SDENB | A13 | I | Serial interface enable. Internal 50kΩ pull-down resistor. |
| SDO | A10 | O | Uni-directional serial interface data in 4 pin mode (register x00, D16). The SDO pin is tri-stated in 3-pin interface mode (default). Internal 50kΩ pull-down resistor. |
| TESTMODE | B13 | – | Factory internal test, do not connect |
| DATA INTERFACE | | | |
| DA[11:0]P/N | P3, N3, P2, N2, P1, N1, M4, M3, M2, M1, L4, L3, L2, L1, K4, K3, K2, K1, J4, J3, J2, J1, H4, H3 | O | ADC A Data Bits 11 (MSB) to 0 (LSB) in DDR output mode. Standard LVDS output. |
| DB[11:0]P/N | E2, E1, D4, D3, D2, D1, C4, C3, C2, C1, B1, A1, B2, A2, B3, A3, B4, A4, B5, A5, B6, A6, B7, A7 | O | ADC B Data Bits 11 (MSB) to 0 (LSB) in DDR output mode. Standard LVDS output. |
| DACLKP/N | H2, H1 | O | DDR differential output data clock for Bus A. Register programmable to provide either rising or falling edge to center of stable data nominal timing. |
| DBCLKP/N | G2, G1 | O | DDR differential output data clock for Bus B. Register programmable to provide either rising or falling edge to center of stable data nominal timing. Optionally Bus B can be latched with DACLKP/N. |
| SYNCOUTP/N | F2, F1, P5, N5 | O | Synchronization output signal for synchronizing multiple ADCs. Can be disabled via SPI. |
| OVRAP/N | M5, L5 | O | Bus A, Overrange indicator, LVDS output. A logic high signals an analog input in excess of the full-scale range. Optional SYNC output. |
| OVRBP/N | D5, C5 | O | Bus B, Overrange indicator, LVDS output. A logic high signals an analog input in excess of the full-scale range. Optional SYNC output. |
| TRIGGERP/N | P10, N10 | I | Trigger used for High resolution output data in feedback mode. Internal 100Ω termination |
| TRDYP/N | G4, G3, P7, N7 | O | Trigger ready output indicator |
| HRESP/N | F4, F3, P6, N6 | O | Indicator for high resolution output data– logic high signals 12bit output data. |
| NC | E3, E4, N4, P4 | – | Don't connect to pin |
| POWER SUPPLY | | | |
| AVDD33 | D12, E12, F12, G12, H12, J12, K12, L12, N12, P12 | I | 3.3V analog supply |
| AVDDC | G14, H14 | I | 1.8V supply for clock input |
| AVDD18 | D10, D11, E11, F11, G11, H11, J11, K11, L10, L11, N11, P11 | I | 1.8V analog supply |
| DVDD | A8, A9, B8, B9, C8, D8, L8, M8, N8, P8 | I | 1.8V supply for digital block |
| DVDDLVS | C6, C7, D6, D7, L6, L7, M6, M7 | I | 1.8V supply for LVDS outputs |
| IOVDD | B10 | I | 1.8V for digital I/Os |
| GND | | I | Ground |

PACKAGE/ORDERING INFORMATION

| PRODUCT | PACKAGE-LEAD | PACKAGE DESIGNATOR | SPECIFIED TEMPERATURE RANGE | ECO PLAN ⁽²⁾ | LEAD/BALL FINISH | PACKAGE MARKING | ORDERING NUMBER | TRANSPORT MEDIA, QUANTITY |
|----------|--------------|--------------------|-----------------------------|----------------------------|------------------|-----------------|-----------------|---------------------------|
| ADS54T02 | 196-BGA | ZAY | –40°C to 85°C | GREEN (RoHS & no Sb/Br) | | ADS54T02I | ADS54T02IZAY | Tray |
| | | | | | | | ADS54T02IZAYR | Tape and Reel |

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)

| | | VALUE | | UNIT |
|--|--|-------|--------------|------|
| | | MIN | MAX | |
| Supply voltage range, AVDD33 | | –0.5 | 4 | V |
| Supply voltage range, AVDDC | | –0.5 | 2.3 | V |
| Supply voltage range, AVDD18 | | –0.5 | 2.3 | V |
| Supply voltage range, DVDD | | –0.5 | 2.3 | V |
| Supply voltage range, DVDDLVD | | –0.5 | 2.3 | V |
| Supply voltage range, IOVDD | | –0.5 | 4 | V |
| Voltage applied to input pins | INA/B_P, INA/B_N | –0.5 | AVDD33 + 0.5 | V |
| | CLKINP, CLKINN | –0.5 | AVDDC + 0.5 | V |
| | SYNCP, SYNCN | –0.5 | AVDD33 + 0.5 | V |
| | SRESET, SDENB, SCLK, SDIO, SDO, ENABLE | –0.5 | IOVDD + 0.5 | V |
| Operating free-air temperature range, T _A | | –40 | 85 | °C |
| Operating junction temperature range, T _J | | | 150 | °C |
| Storage temperature range | | –65 | 150 | °C |
| ESD, Human Body Model | | | 2 | kV |

THERMAL INFORMATION

| THERMAL METRIC ⁽¹⁾ | | ADS54T02 | UNITS |
|-------------------------------|---|----------|-------|
| | | QFN | |
| | | 196 PINS | |
| θ_{JA} | Junction-to-ambient thermal resistance ⁽²⁾ | 37.6 | °C/W |
| θ_{JCTop} | Junction-to-case (top) thermal resistance ⁽³⁾ | 6.8 | |
| θ_{JB} | Junction-to-board thermal resistance ⁽⁴⁾ | 16.8 | |
| ψ_{JT} | Junction-to-top characterization parameter ⁽⁵⁾ | 0.2 | |
| ψ_{JB} | Junction-to-board characterization parameter ⁽⁶⁾ | 16.4 | |
| θ_{JCbott} | Junction-to-case (bottom) thermal resistance ⁽⁷⁾ | N/A | |

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

(2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.

(3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

(4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.

(5) The junction-to-top characterization parameter, ψ_{JT} , estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA} , using a procedure described in JESD51-2a (sections 6 and 7).

(6) The junction-to-board characterization parameter, ψ_{JB} , estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA} , using a procedure described in JESD51-2a (sections 6 and 7).

(7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

| | | MIN | NOM | MAX | UNIT |
|-------|---|-----|-----|-----|------|
| T_J | Recommended operating junction temperature | | | 105 | °C |
| | Maximum rated operating junction temperature ⁽¹⁾ | 125 | | | |
| T_A | Recommended free-air temperature | –40 | 25 | 85 | °C |

(1) Prolonged use at this junction temperature may increase the device failure-in-time (FIT) rate.

ELECTRICAL CHARACTERISTICS

Typical values at $T_A = 25^\circ\text{C}$, full temperature range is $T_{\text{MIN}} = -40^\circ\text{C}$ to $T_{\text{MAX}} = 85^\circ\text{C}$, ADC sampling rate = 750Msps, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVD/IOVDD = 1.8V, –1dBFS differential input (unless otherwise noted).

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|------------------------------------|---------------------------------|--|------|------|------|-------|
| ADC Clock Frequency | | | | 750 | | MSPS |
| Resolution | | | 12 | | | Bits |
| SUPPLY | | | | | | |
| AVDD33 | | | 3.15 | 3.3 | 3.45 | V |
| AVDDC, AVDD18, DVDD, DVDDLVS | | | 1.7 | 1.8 | 1.9 | V |
| IOVDD | | | 1.7 | 1.8 | 3.45 | V |
| POWER SUPPLY | | | | | | |
| I _{AVDD33} | 3.3V Analog supply current | | | 303 | 350 | mA |
| I _{AVDD18} | 1.8V Analog supply current | | | 103 | 120 | mA |
| I _{AVDDC} | 1.8V Clock supply current | | | 41 | 60 | mA |
| I _{DVDD} | 1.8V Digital supply current | Auto Correction Enabled | | 323 | 400 | mA |
| I _{DVDD} | 1.8V Digital supply current | Auto Correction Disabled | | 155 | | mA |
| I _{DVDD} | 1.8V Digital supply current | Auto Correction Disabled, decimation filter enabled | | 184 | | mA |
| I _{DVDDLVS} | 1.8V LVDS supply current | | | 125 | 150 | mA |
| I _{IOVDD} | 1.8V I/O Voltage supply current | | | 1 | 2 | mA |
| P _{dis} | Total power dissipation | Auto Correction Enabled, decimation filter disabled | | 2.1 | 2.5 | W |
| P _{dis} | Total power dissipation | Auto Correction Disabled, decimation filter disabled | | 1.76 | | W |
| PSRR | | 250kHz to 500MHz | 40 | | | dB |
| Shut-down power dissipation | | | | 7 | | mW |
| Shut-down wake up time | | | | 2.5 | | ms |
| Standby power dissipation | | | | 7 | | mW |
| Standby wake up time | | | | 100 | | μs |
| Deep-sleep mode power dissipation | | Auto correction disabled | | 282 | | mW |
| | | Auto correction enabled | | 358 | | mW |
| Deep-sleep mode wakeup time | | | | 20 | | μs |
| Light-sleep mode power dissipation | | Auto correction disabled | | 549 | | mW |
| | | Auto correction enabled | | 665 | | mW |
| Light-sleep mode wakeup time | | | | 2 | | μs |

ELECTRICAL CHARACTERISTICS

Typical values at $T_A = 25^\circ\text{C}$, full temperature range is $T_{\text{MIN}} = -40^\circ\text{C}$ to $T_{\text{MAX}} = 85^\circ\text{C}$, ADC sampling rate = 750Mps, 50% clock duty cycle, AVDD3V = 3.3V, AVDD/DRVDD/IOVDD = 1.8V, –1dBFS differential input (unless otherwise noted).

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|--------------------------------|-----------------------------------|-----|----------|-----|-----------------|
| ANALOG INPUTS | | | | | |
| Differential input full-scale | | | 1.0 1.25 | | V _{pp} |
| Input common mode voltage | | | 1.9 ±0.1 | | V |
| Input resistance | Differential at DC | | 1 | | kΩ |
| Input capacitance | Each input to GND | | 2 | | pF |
| VCM common mode voltage output | | | 1.9 | | V |
| Analog input bandwidth (3dB) | | | 1200 | | MHz |
| DYNAMIC ACCURACY | | | | | |
| Offset Error | Auto Correction Disabled | –20 | –7.5 | 20 | mV |
| | Auto Correction Enabled | –1 | 0 | 1 | mV |
| Offset temperature coefficient | | | –611 | | μV/°C |
| Gain error | | –5 | | 5 | %FS |
| Gain temperature coefficient | | | 0.005 | | %FS/°C |
| Differential nonlinearity | $f_{\text{IN}} = 230 \text{ MHz}$ | –1 | ±0.9 | 2 | LSB |
| Integral nonlinearity | $f_{\text{IN}} = 230 \text{ MHz}$ | –5 | ±1.5 | 5 | LSB |
| CLOCK INPUT | | | | | |
| Input clock frequency | | | 750 | | MHz |
| Input clock amplitude | | | 2 | | V _{pp} |
| Input clock duty cycle | | 40% | 50% | 60% | |
| Internal clock biasing | | | 0.9 | | V |

ELECTRICAL CHARACTERISTICS

Typical values at $T_A = 25^\circ\text{C}$, full temperature range is $T_{\text{MIN}} = -40^\circ\text{C}$ to $T_{\text{MAX}} = 85^\circ\text{C}$, ADC sampling rate = 750MSPS, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVS/IOVDD = 1.8V, –1dBFS differential input (unless otherwise noted).

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | MIN | TYP | MAX | UNITS |
|---|--|--|---------|------|-----|----------|------|-----|-------|
| Auto Correction | | | Enabled | | | Disabled | | | Vpp |
| DYNAMIC AC CHARACTERISTICS ⁽¹⁾ – Burst Mode Enabled: 12bit High Resolution Output Data | | | | | | | | | |
| SNR | Signal to Noise Ratio | f _{IN} = 10 MHz | | 61.1 | | | 61.2 | | dBFS |
| | | f _{IN} = 100 MHz | | 61 | | | 61.1 | | |
| | | f _{IN} = 230 MHz | 59 | 60.7 | | | 60.9 | | |
| | | f _{IN} = 450 MHz | | 60 | | | 60.7 | | |
| | | f _{IN} = 700 MHz | | 58.9 | | | 60 | | |
| HD2,3 | Second and third harmonic distortion | f _{IN} = 10 MHz | | 81 | | | 85 | | dBc |
| | | f _{IN} = 100 MHz | | 76 | | | 81 | | |
| | | f _{IN} = 230 MHz | 68 | 78 | | | 78 | | |
| | | f _{IN} = 450 MHz | | 79 | | | 78 | | |
| | | f _{IN} = 700 MHz | | 76 | | | 78 | | |
| Non HD2,3 | Spur Free Dynamic Range (excluding second and third harmonic distortion and Fs/2 – F _{IN} spur) | f _{IN} = 10 MHz | | 81 | | | 83 | | dBc |
| | | f _{IN} = 100 MHz | | 81 | | | 82 | | |
| | | f _{IN} = 230 MHz | 68 | 79 | | | 81 | | |
| | | f _{IN} = 450 MHz | | 77 | | | 81 | | |
| | | f _{IN} = 700 MHz | | 73 | | | 82 | | |
| IL | Fs/2-Fin interleaving spur | f _{IN} = 10 MHz | | 90 | | | 86 | | dBc |
| | | f _{IN} = 100 MHz | | 83 | | | 83 | | |
| | | f _{IN} = 230 MHz | 65 | 78 | | | 77 | | |
| | | f _{IN} = 450 MHz | | 75 | | | 74 | | |
| | | f _{IN} = 700 MHz | | 73 | | | 69 | | |
| SINAD | Signal to noise and distortion ratio | f _{IN} = 10 MHz | | 61 | | | 61.1 | | dBc |
| | | f _{IN} = 100 MHz | | 60.8 | | | 61 | | |
| | | f _{IN} = 230 MHz | 57.5 | 60.5 | | | 60.8 | | |
| | | f _{IN} = 450 MHz | | 59.8 | | | 60.3 | | |
| | | f _{IN} = 700 MHz | | 58.4 | | | 59.4 | | |
| THD | Total Harmonic Distortion | f _{IN} = 10 MHz | | 76 | | | 76.5 | | dBc |
| | | f _{IN} = 100 MHz | | 73 | | | 76 | | |
| | | f _{IN} = 230 MHz | 66 | 74 | | | 74 | | |
| | | f _{IN} = 450 MHz | | 74 | | | 73 | | |
| | | f _{IN} = 700 MHz | | 72 | | | 74 | | |
| IMD3 | Inter modulation distortion | F _{in} = 129.5 and 130.5MHz, -7dBFS | | 82 | | | 83 | | dBFS |
| | | F _{in} = 349.5 and 350.5MHz, -7dBFS | | 76 | | | 77 | | |
| | Crosstalk | | | 90 | | | 90 | | dB |
| ENOB | Effective number of bits | f _{IN} = 230 MHz | | 9.8 | | | 9.8 | | LSB |

(1) SFDR and SNR calculations do not include the DC or $F_s/2$ bins when Auto Correction is disabled.

ELECTRICAL CHARACTERISTICS

Typical values at $T_A = 25^\circ\text{C}$, full temperature range is $T_{\text{MIN}} = -40^\circ\text{C}$ to $T_{\text{MAX}} = 85^\circ\text{C}$, ADC sampling rate = 750Mpsps, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVS/IOVDD = 1.8V, –1dBFS differential input (unless otherwise noted).

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|--------------------------------------|---|-----|-----|-----|-----------------------|
| OVER-DRIVE RECOVERY ERROR | | | | | |
| Input overload recovery | Recovery to within 5% (of final value) for 6dB overload with sine wave input | | 2 | | ns |
| SAMPLE TIMING CHARACTERISTICS | | | | | |
| rms Aperture Jitter | Sample uncertainty | | 100 | | fs rms |
| Data Latency | ADC sample to digital output, auto correction disabled | | 38 | | Clock Cycles |
| | ADC sample to digital output, auto correction enabled | | 50 | | |
| | ADC sample to digital output, Decimation filter enabled, Auto correction disabled | | 74 | | Sampling clock Cycles |
| Over-range Latency | ADC sample to over-range output | | 12 | | Clock Cycles |

ELECTRICAL CHARACTERISTICS

The DC specifications refer to the condition where the digital outputs are not switching, but are permanently at a valid logic level 0 or 1. AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVS/IOVDD = 1.8V

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|--|-----------------------------|---|--------------|------|-------|-------|
| DIGITAL INPUTS – SRESET, SCLK, SDENB, SDIO, ENABLE | | | | | | |
| High-level input voltage | | All digital inputs support 1.8V and 3.3V logic levels. | 0.7 x IOVDD | | V | |
| Low-level input voltage | | | 0.3 x IOVDD | | V | |
| High-level input current | | | –50 | 200 | μA | |
| Low-level input current | | | –50 | 50 | μA | |
| Input capacitance | | | 5 | | pF | |
| DIGITAL OUTPUTS – SDO | | | | | | |
| High-level output voltage | | Iload = -100uA | IOVDD – 0.2 | | V | |
| | | Iload = -2mA | 0.8 x IOVDD | | | |
| Low-level output voltage | | Iload = 100uA | 0.2 | | V | |
| | | Iload = 2mA | 0.22 x IOVDD | | | |
| DIGITAL INPUTS – SYNC/N, TRIGGER/N | | | | | | |
| V _{ID} | Differential input voltage | | 250 | 350 | 450 | mV |
| V _{CM} | Input common mode voltage | | 1.125 | 1.2 | 1.375 | V |
| t _{SU} | | | 500 | | | ps |
| DIGITAL OUTPUTS – DA[11:0]P/N, DACLK/N, OVRAP/N, SYNCOUTP/N, TRDYP/N, HRESP/N, DB[11:0]P/N, DBCLKP/N, OVRBP/N, | | | | | | |
| V _{OD} | Output differential voltage | Iout = 3.5mA | 250 | 350 | 450 | mV |
| V _{OCM} | Output common mode voltage | Iout = 3.5mA | 1.125 | 1.25 | 1.375 | V |
| t _{suA} | | F _s = 750Msps, Data valid to zero-crossing of DACLK | 320 | 400 | | ps |
| t _{hA} | | F _s = 750Msps, Zero-crossing of DACLK to data becoming invalid | 250 | 320 | | ps |
| t _{suB} | | F _s = 750Msps, Data valid to zero-crossing of DBCLK | 400 | 460 | | ps |
| t _{hB} | | F _s = 750Msps, Zero-crossing of DBCLK to data becoming invalid | 300 | 370 | | ps |

ELECTRICAL CHARACTERISTICS (continued)

The DC specifications refer to the condition where the digital outputs are not switching, but are permanently at a valid logic level 0 or 1. AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVDSD/IOVDD = 1.8V

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|------------|--|------|------|------|-------|
| t_{PD} | $F_s = 750\text{Mps}$, CLKIN falling edge to DACLK, DBCLK rising edge | 3.36 | 3.69 | 3.92 | ns |
| t_{RISE} | 10% - 90% | 100 | 150 | 200 | ps |
| t_{FALL} | 90% - 10% | 100 | 150 | 200 | ps |

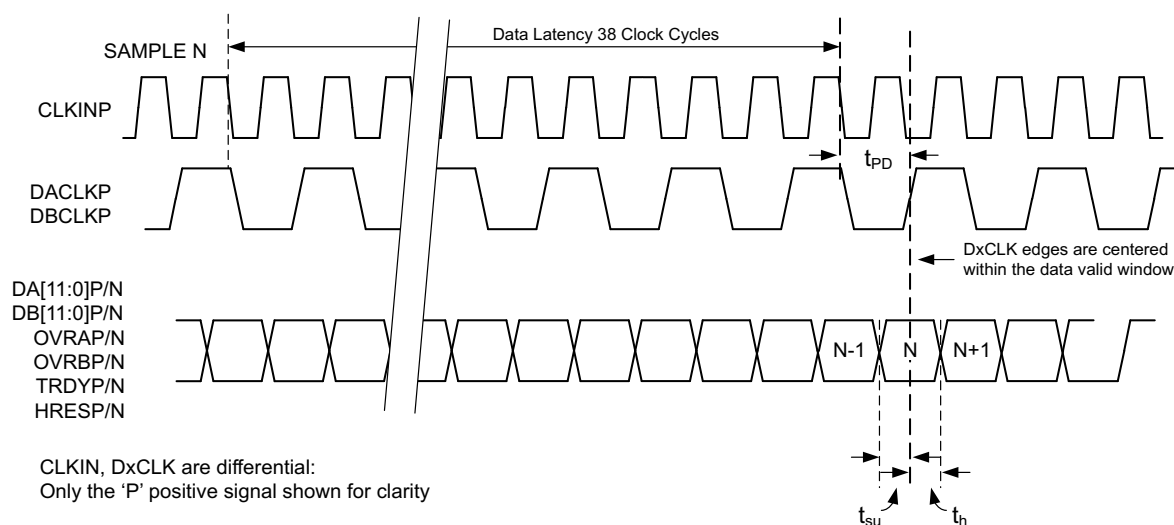


Figure 3. Timing Diagram for 12-bit DDR Output

TYPICAL CHARACTERISTICS

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{\text{MIN}} = -40^\circ\text{C}$ to $T_{\text{MAX}} = +85^\circ\text{C}$, ADC sampling rate = 750Msps, 50% clock duty cycle, $\text{AVDD33} = 3.3\text{V}$, $\text{AVDDC}/\text{AVDD18}/\text{DVDD}/\text{DVDDLVD}/\text{IOVDD} = 1.8\text{V}$, -1dBFS differential input, unless otherwise noted.

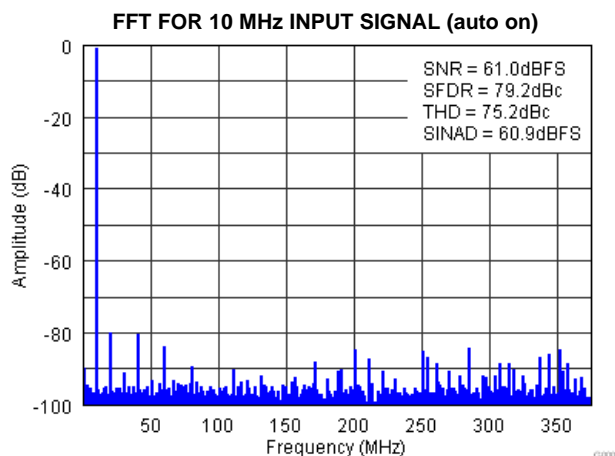


Figure 4.

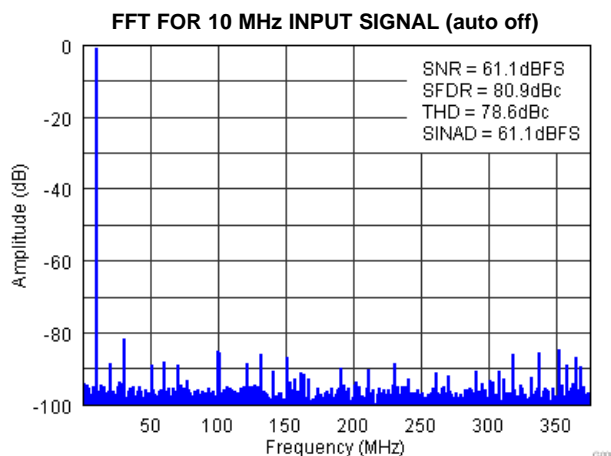


Figure 5.

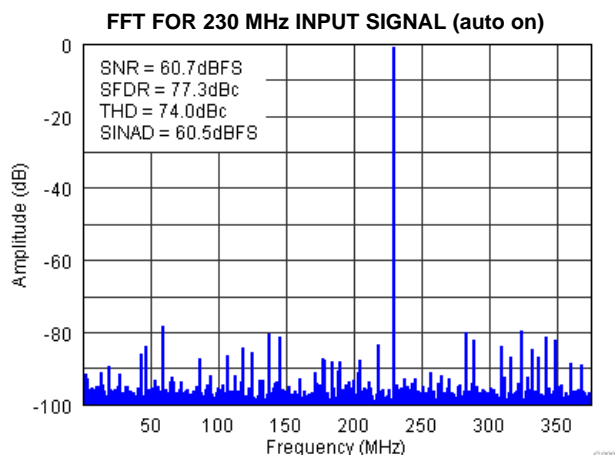


Figure 6.

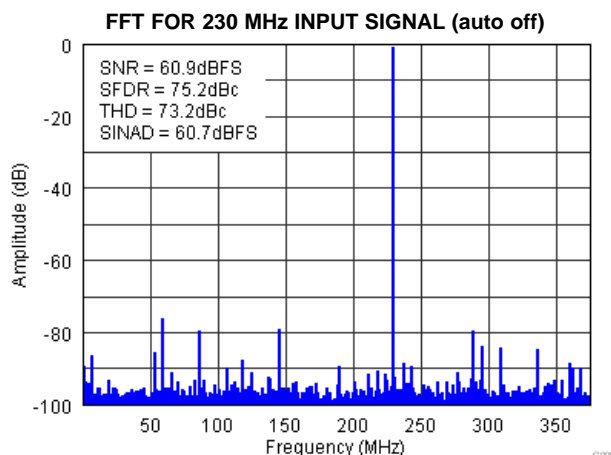


Figure 7.

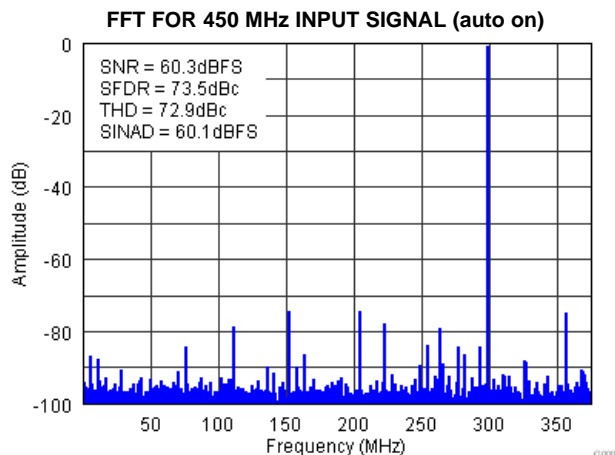


Figure 8.

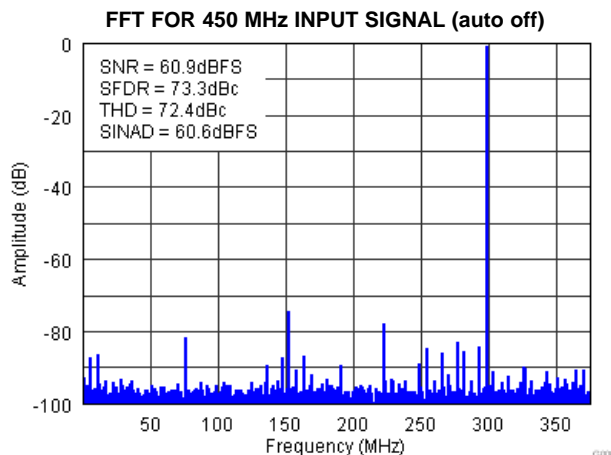


Figure 9.

TYPICAL CHARACTERISTICS (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{\text{MIN}} = -40^\circ\text{C}$ to $T_{\text{MAX}} = +85^\circ\text{C}$, ADC sampling rate = 750MSPS, 50% clock duty cycle, $\text{AVDD33} = 3.3\text{V}$, $\text{AVDDC}/\text{AVDD18}/\text{DVDD}/\text{DVDDLVS}/\text{IOVDD} = 1.8\text{V}$, -1dBFS differential input, unless otherwise noted.

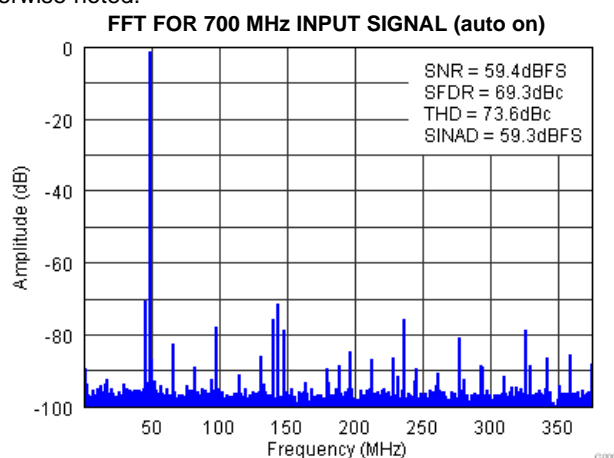


Figure 10.

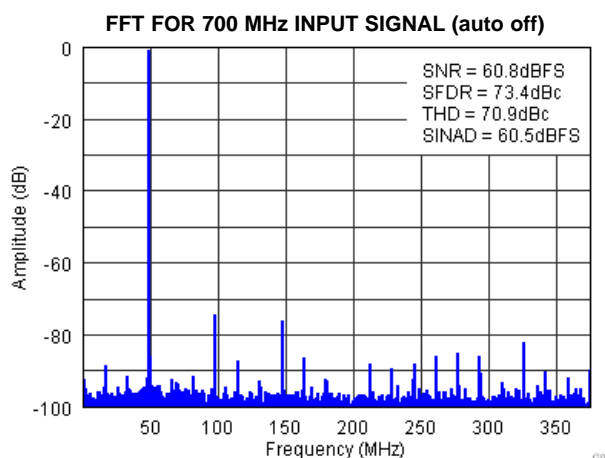


Figure 11.

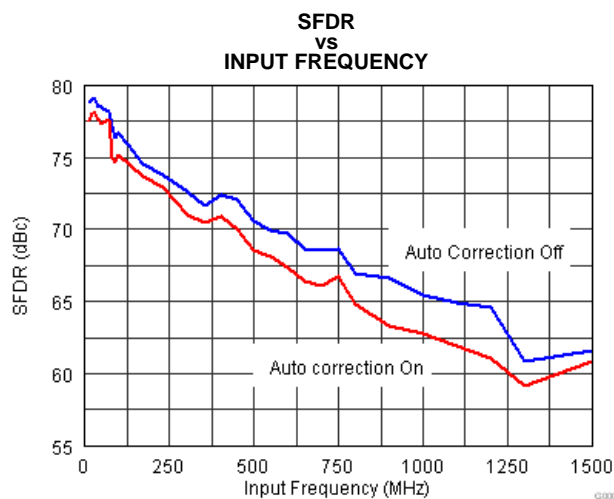


Figure 12.

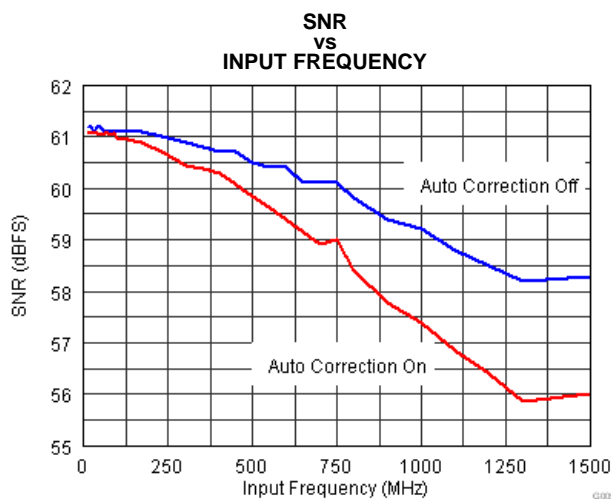


Figure 13.

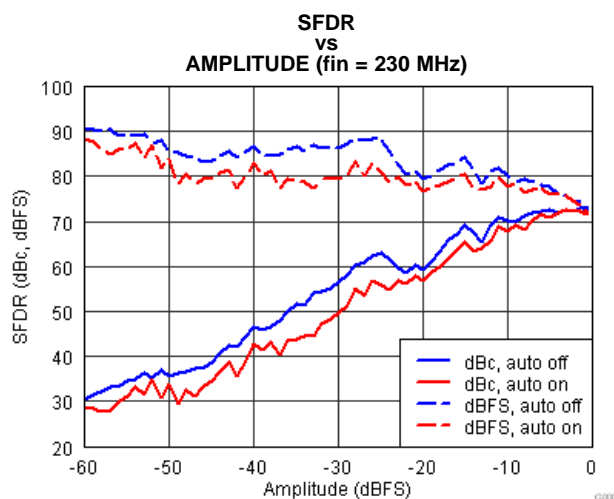


Figure 14.

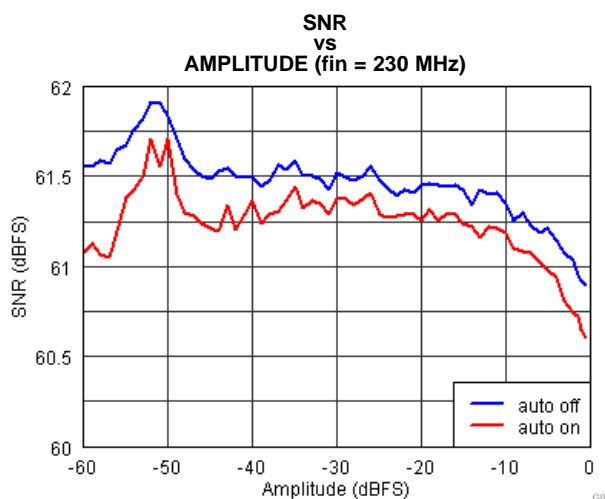


Figure 15.

TYPICAL CHARACTERISTICS (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{\text{MIN}} = -40^\circ\text{C}$ to $T_{\text{MAX}} = +85^\circ\text{C}$, ADC sampling rate = 750MSPS, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVS/IOVDD = 1.8V, -1dBFS differential input, unless otherwise noted.

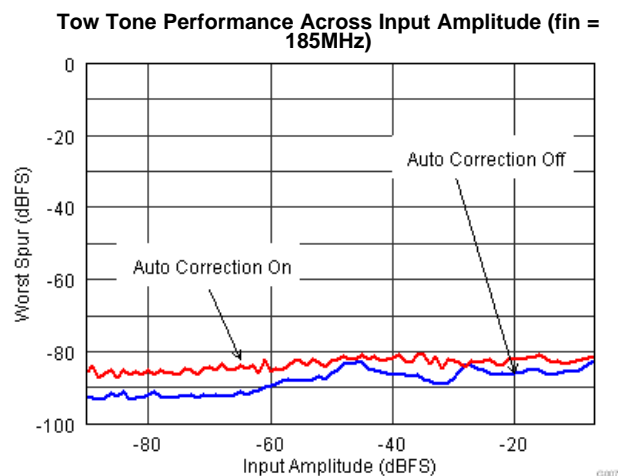


Figure 16.

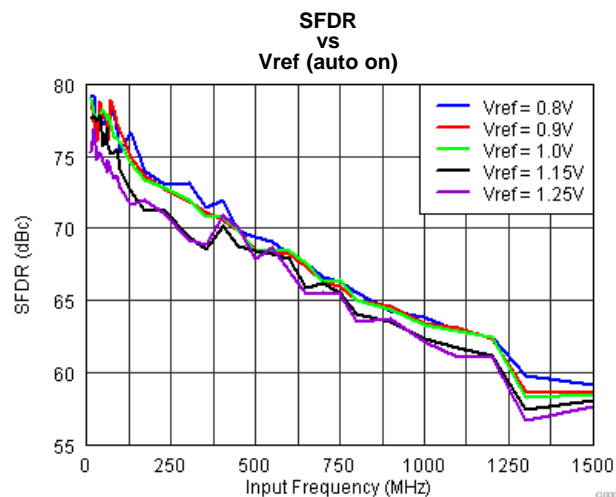


Figure 17.

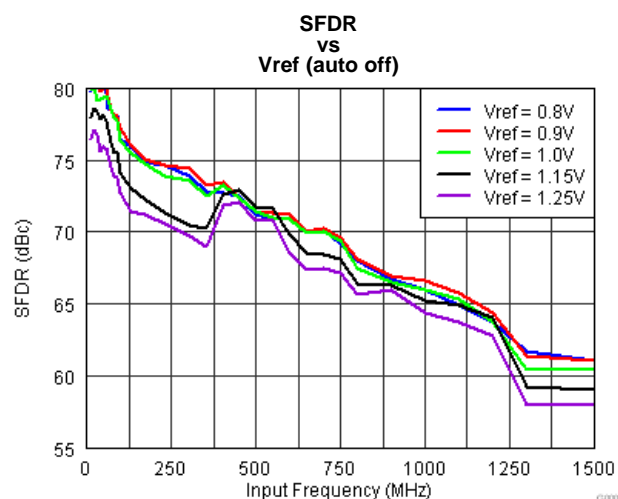


Figure 18.

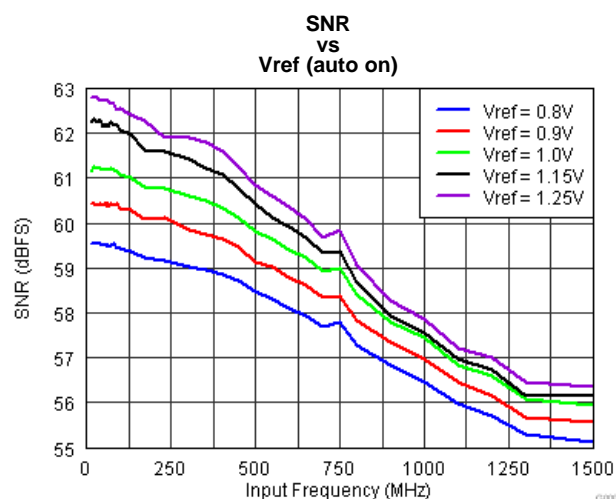


Figure 19.

TYPICAL CHARACTERISTICS (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{\text{MIN}} = -40^\circ\text{C}$ to $T_{\text{MAX}} = +85^\circ\text{C}$, ADC sampling rate = 750Mps, 50% clock duty cycle, $\text{AVDD33} = 3.3\text{V}$, $\text{AVDDC}/\text{AVDD18}/\text{DVDD}/\text{DVDDLVS}/\text{IOVDD} = 1.8\text{V}$, -1dBFS differential input, unless otherwise noted.

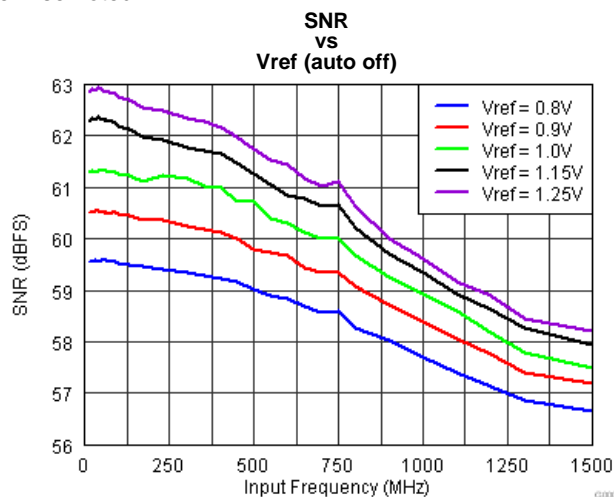


Figure 20.

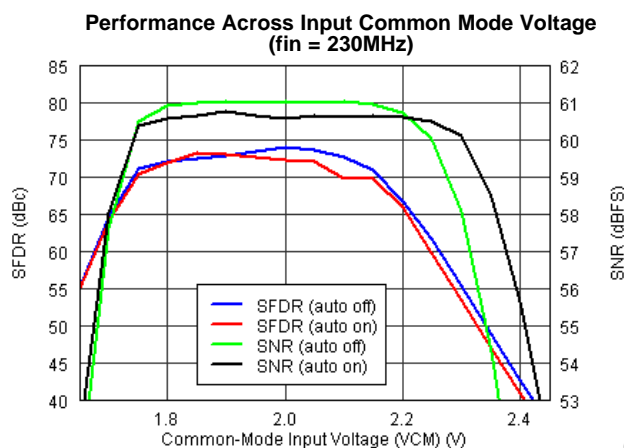


Figure 21.

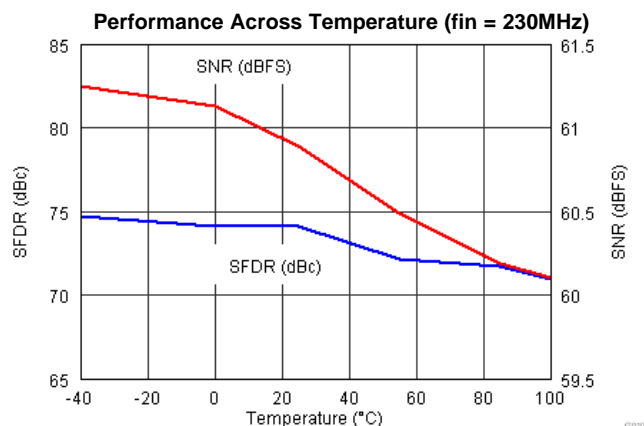


Figure 22.

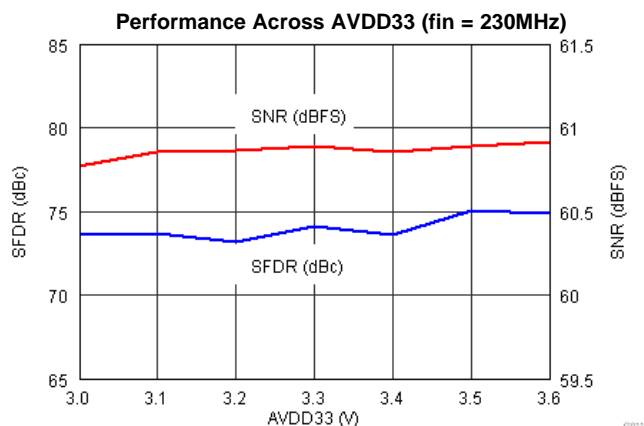


Figure 23.

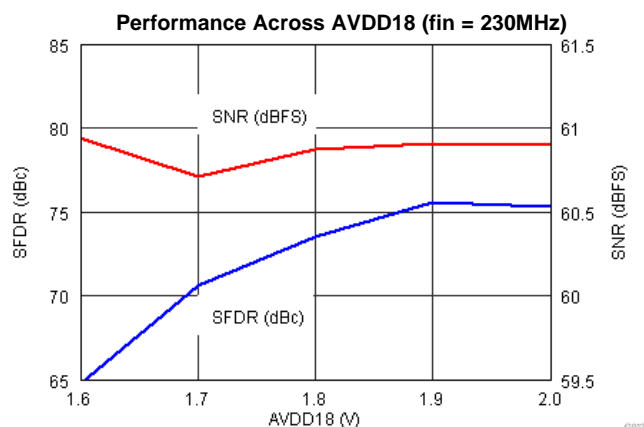


Figure 24.

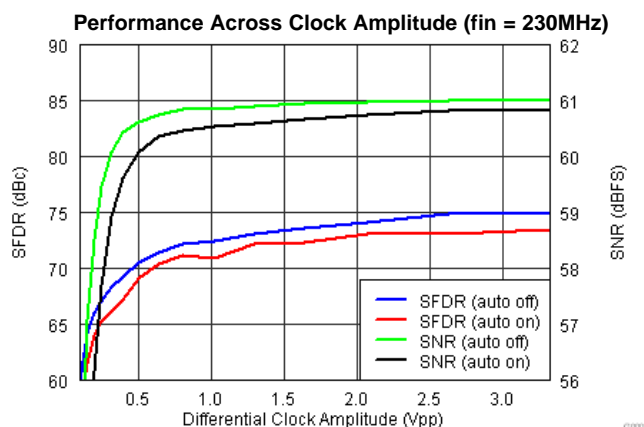


Figure 25.

TYPICAL CHARACTERISTICS (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{\text{MIN}} = -40^\circ\text{C}$ to $T_{\text{MAX}} = +85^\circ\text{C}$, ADC sampling rate = 750Mps, 50% clock duty cycle, $\text{AVDD33} = 3.3\text{V}$, $\text{AVDDC}/\text{AVDD18}/\text{DVDD}/\text{DVDDLVS}/\text{IOVDD} = 1.8\text{V}$, -1dBFS differential input, unless otherwise noted.

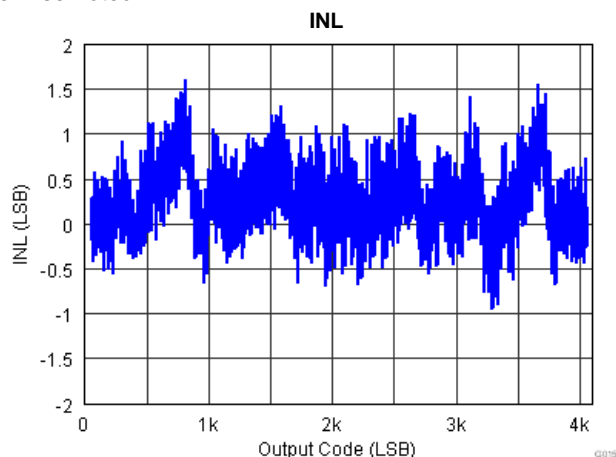


Figure 26.

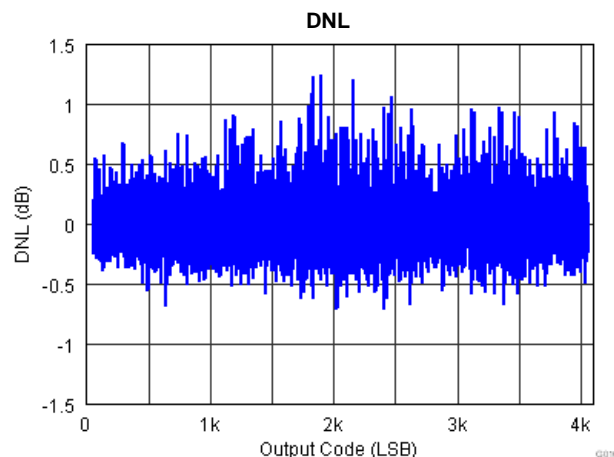


Figure 27.

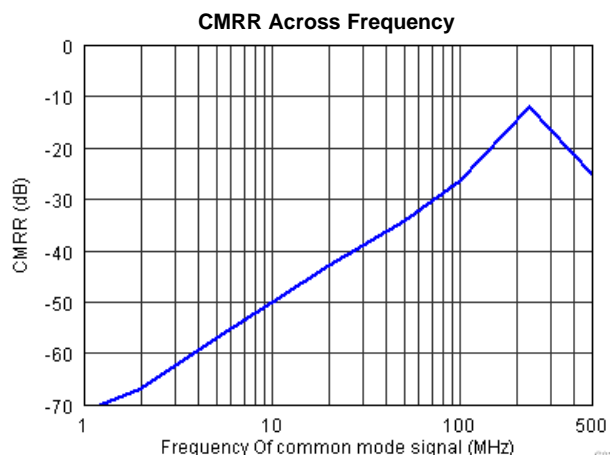


Figure 28.

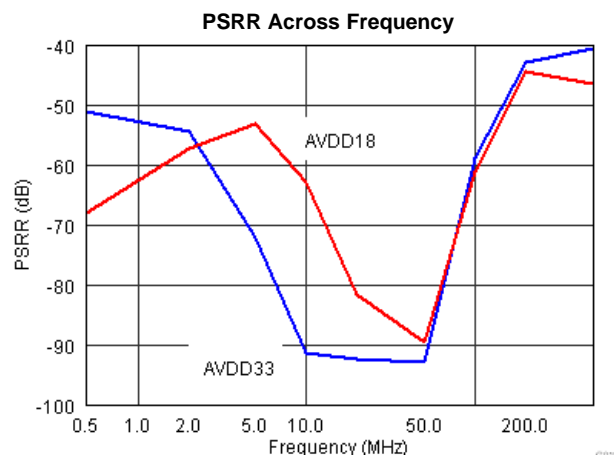


Figure 29.

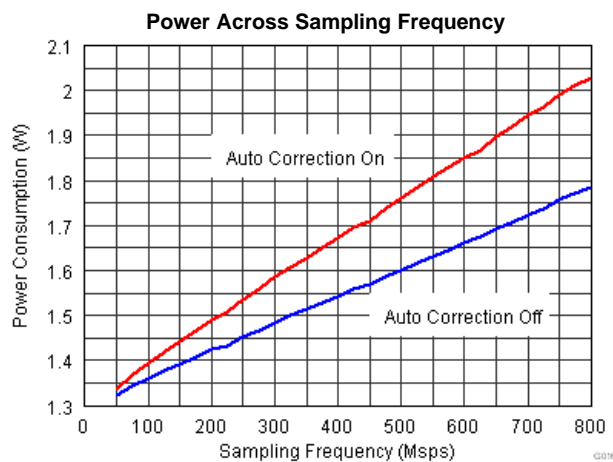


Figure 30.

TYPICAL CHARACTERISTICS (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{\text{MIN}} = -40^\circ\text{C}$ to $T_{\text{MAX}} = +85^\circ\text{C}$, ADC sampling rate = 750MSPS, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVD/IOVDD = 1.8V, -1dBFS differential input, unless otherwise noted.

SFDR Across Input and Sampling Frequencies (auto on)

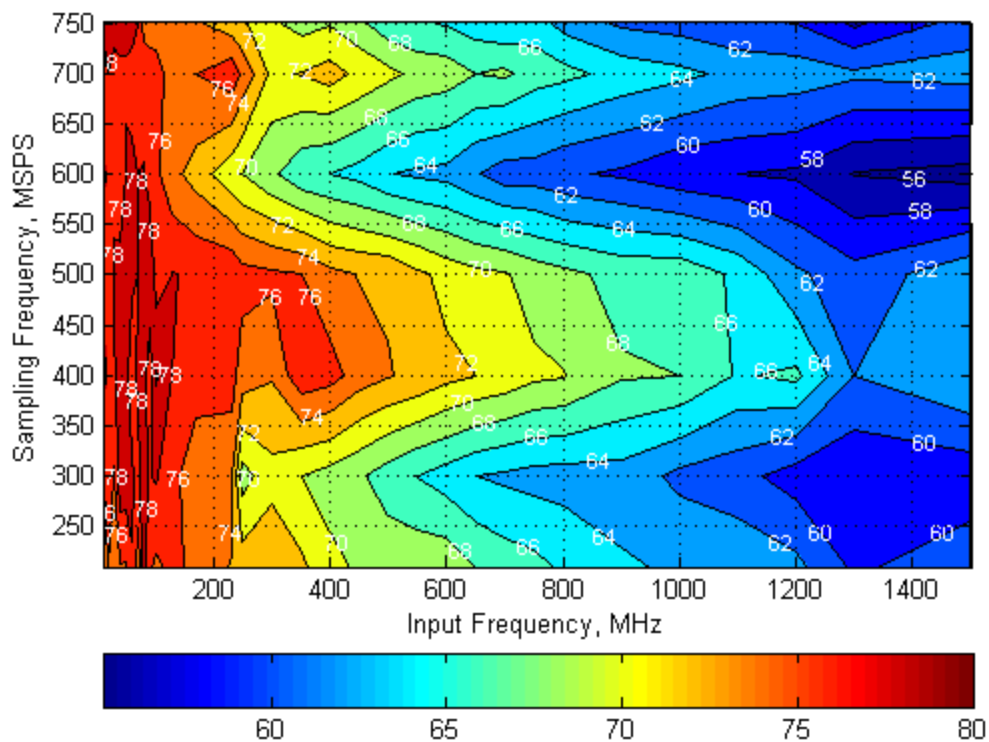


Figure 31.

TYPICAL CHARACTERISTICS (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{\text{MIN}} = -40^\circ\text{C}$ to $T_{\text{MAX}} = +85^\circ\text{C}$, ADC sampling rate = 750Mps, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVD/IOVDD = 1.8V, -1dBFS differential input, unless otherwise noted.

SFDR Across Input and Sampling Frequencies (auto off)

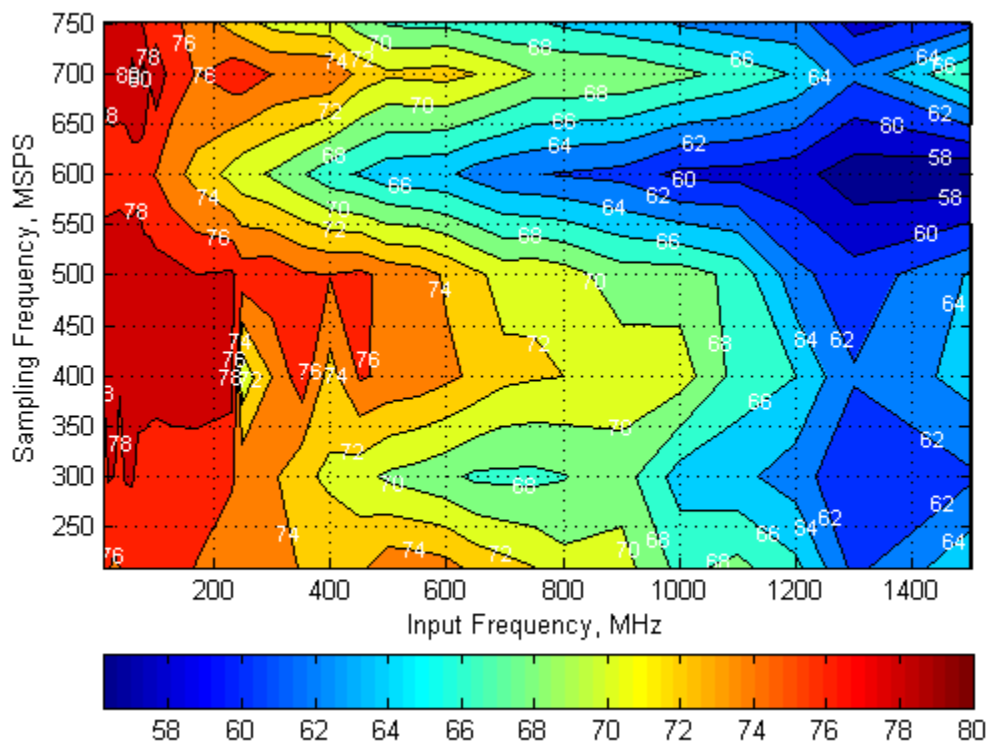


Figure 32.

TYPICAL CHARACTERISTICS (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{\text{MIN}} = -40^\circ\text{C}$ to $T_{\text{MAX}} = +85^\circ\text{C}$, ADC sampling rate = 750MSPs, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVS/IOVDD = 1.8V, -1dBFS differential input, unless otherwise noted.

SNR Across Input and Sampling Frequencies (auto on)

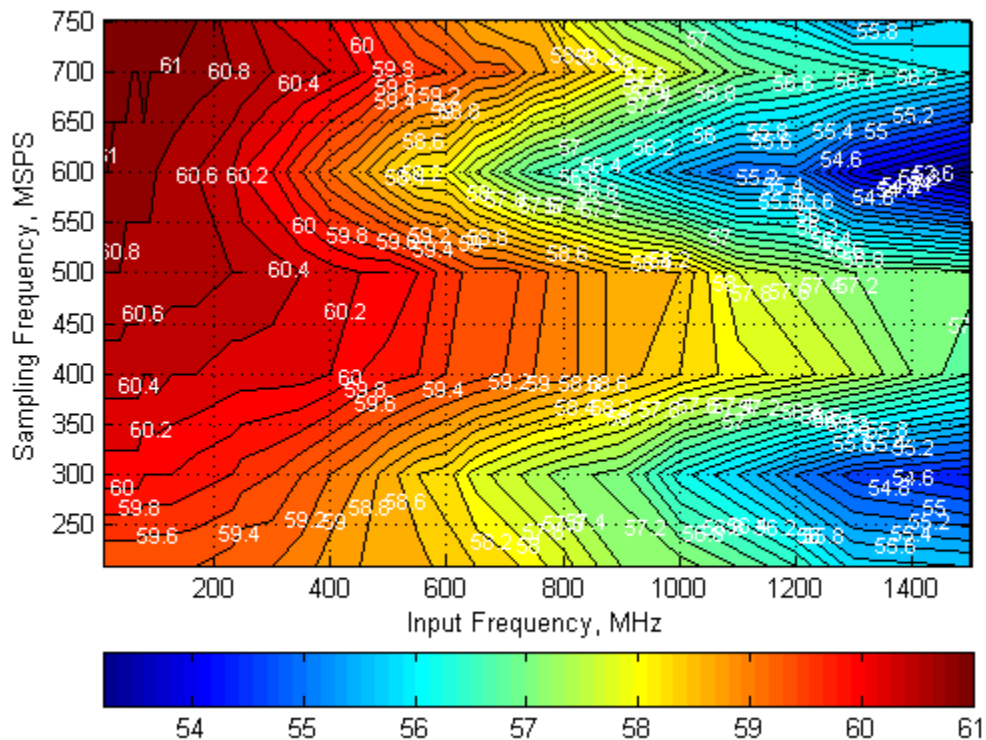


Figure 33.

TYPICAL CHARACTERISTICS (continued)

Typical values at $T_A = +25^\circ\text{C}$, full temperature range is $T_{\text{MIN}} = -40^\circ\text{C}$ to $T_{\text{MAX}} = +85^\circ\text{C}$, ADC sampling rate = 750MSPs, 50% clock duty cycle, AVDD33 = 3.3V, AVDDC/AVDD18/DVDD/DVDDLVDs/IOVDD = 1.8V, -1dBFS differential input, unless otherwise noted.

SNR Across Input and Sampling Frequencies (auto on)

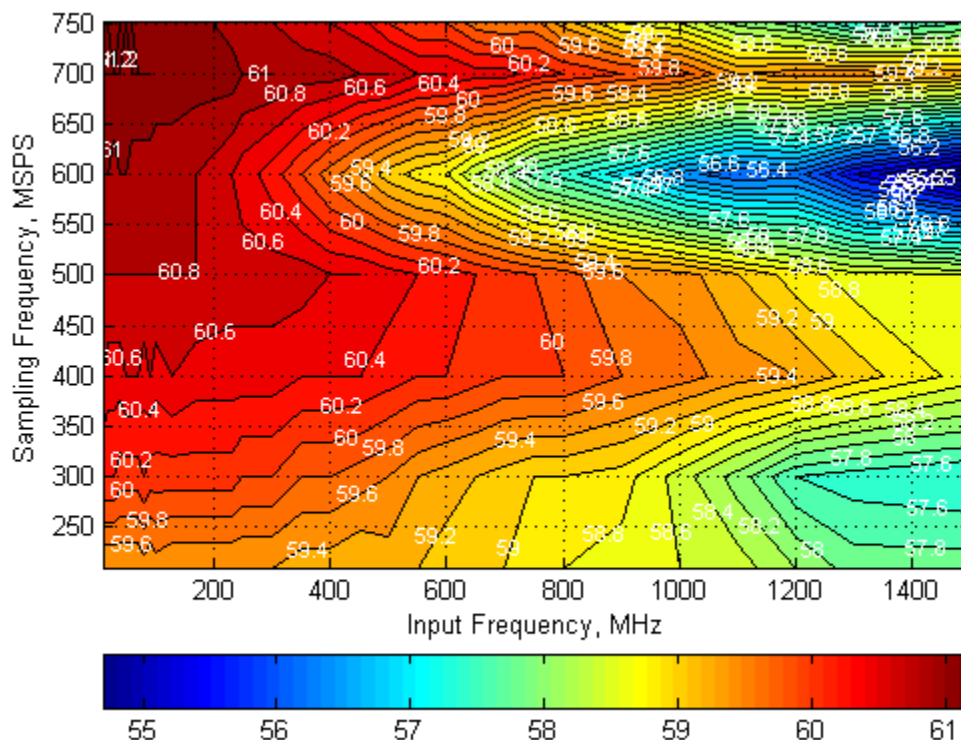


Figure 34.

FEATURES

POWER DOWN MODES

The ADS54T02 can be configured via SPI write (address x37) to a stand-by, light or deep sleep power mode which is controlled by the ENABLE pin. The sleep modes are active when the ENABLE pin goes low. Different internal functions stay powered up which results in different power consumption and wake up time between the two sleep modes.

| Sleep mode | Wake up time | Power Consumption Auto correction disabled | Power Consumption Auto correction enabled |
|--------------------|--------------|--|---|
| Complete Shut Down | 2.5 ms | 7 mW | 7 mW |
| Stand-by | 100 μ s | 7 mW | 7 mW |
| Deep Sleep | 20 μ s | 292 mW | 358 mW |
| Light Sleep | 2 μ s | 549 mW | 655 mW |

TEST PATTERN OUTPUT

The ADS54T02 can be configured to output different test patterns that can be used to verify the digital interface is connected and working properly. To enable the test pattern mode, the high performance mode 1 has to be disabled first via SPI register write. Then different test patterns can be selected by configuring registers x3C, x3D and x3E. All three registers must be configured for the test pattern to work properly.

First set HP1 = 0 (Addr 0x01, D01)

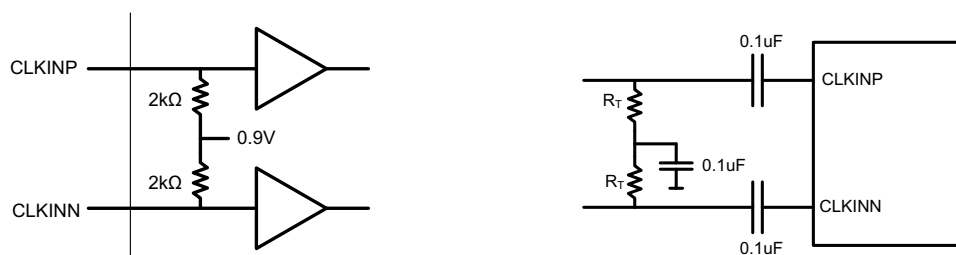
| Register Address | All 0s | All 1s | Toggle (0xAAA => 0x555) | Toggle (0xFFFF => 0x000) |
|------------------|--------|--------|-------------------------|--------------------------|
| 0x3C | 0x8000 | 0xBFFC | 0x9554 | 0xBFFC |
| 0x3D | 0x0000 | 0x3FFC | 0x2AA8 | 0x0000 |
| 0x3E | 0x0000 | 0x3FFC | 0x1554 | 0x3FFC |

| Register Address | Custom Pattern | | | | | | | | | | | | | | | |
|------------------|----------------|-----|-----|-----|-----|-----|----|----|----|----|----|----|----|----|----|----|
| | D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| x3C | 1 | 0 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 | 0 | 0 |
| x3D | 0 | 0 | | | | | | | | | | | | | 0 | 0 |
| x3E | 0 | 0 | | | | | | | | | | | | | 0 | 0 |

For normal operation, set HP1 = 1 (Addr 0x01, D01) and 0x3C, 0x3D, 0x3E all to 0.

CLOCK INPUT

The ADS54T02 clock input can be driven differentially with a sine wave, LVPECL or LVDS source with little or no difference in performance. The common mode voltage of the clock input is set to 0.9V using internal 2k Ω resistors. This allows for AC coupling of the clock inputs. The termination resistors should be placed as close as possible to the clock inputs in order to minimize signal reflections and jitter degradation.



Recommended differential clock driving circuit

Figure 35. Recommended Differential Clock Driving Circuit

SNR AND CLOCK JITTER

The signal to noise ratio of the ADC is limited by three different factors: the quantization noise is typically not noticeable in pipeline converters and is 72dB for a 12bit ADC. The thermal noise limits the SNR at low input frequencies while the clock jitter sets the SNR for higher input frequencies.

$$\text{SNR}_{\text{ADC}}[\text{dBc}] = -20 \times \log \sqrt{\left(10 - \frac{\text{SNR}_{\text{Quantization_Noise}}}{20}\right)^2 + \left(10 - \frac{\text{SNR}_{\text{ThermalNoise}}}{20}\right)^2 + \left(10 - \frac{\text{SNR}_{\text{Jitter}}}{20}\right)^2} \quad (1)$$

The SNR limitation due to sample clock jitter can be calculated as following:

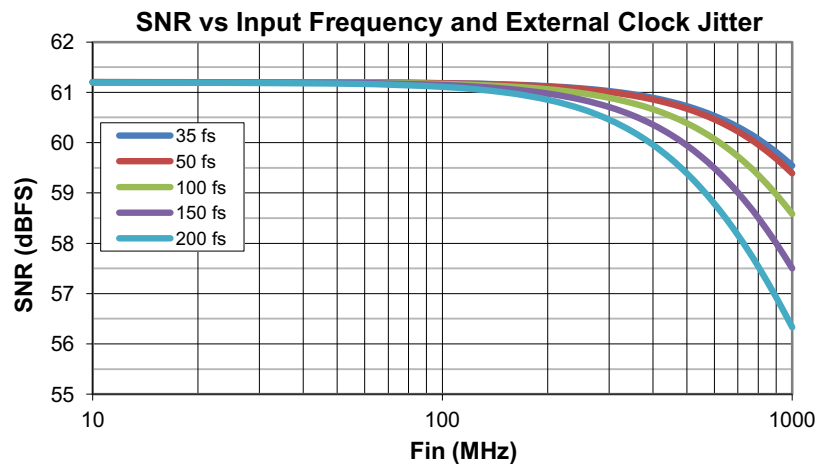
$$\text{SNR}_{\text{Jitter}}[\text{dBc}] = -20 \times \log(2\pi \times f_{\text{IN}} \times t_{\text{Jitter}}) \quad (2)$$

The total clock jitter (TJitter) has three components – the internal aperture jitter (100fs for ADS54T02) which is set by the noise of the clock input buffer, the external clock jitter and the jitter from the analog input signal. It can be calculated as following:

$$T_{\text{Jitter}} = \sqrt{(T_{\text{Jitter,Ext.Clock_Input}})^2 + (T_{\text{Aperture_ADC}})^2} \quad (3)$$

External clock jitter can be minimized by using high quality clock sources and jitter cleaners as well as bandpass filters at the clock input while a faster clock slew rate improves the ADC aperture jitter.

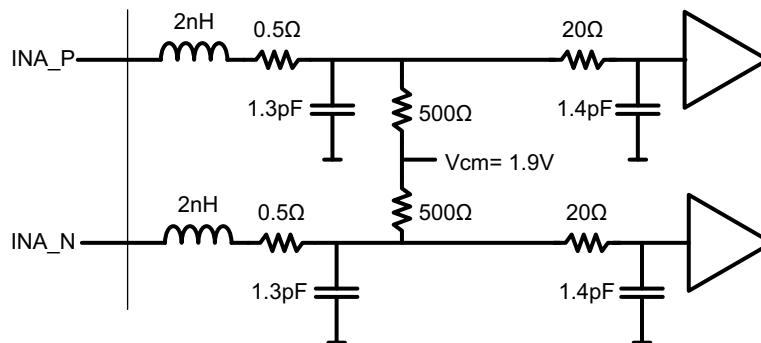
The ADS54T02 has a thermal noise of 61.2 dBFS and internal aperture jitter of 100fs. The SNR depending on amount of external jitter for different input frequencies is shown in the following figure.



ANALOG INPUTS

The ADS54T02 analog signal inputs are designed to be driven differentially. The analog input pins have internal analog buffers that drive the sampling circuit. As a result of the analog buffer, the input pins present a high impedance input across a very wide frequency range to the external driving source which enables great flexibility in the external analog filter design as well as excellent 50Ω matching for RF applications. The buffer also helps to isolate the external driving circuit from the internal switching currents of the sampling circuit which results in a more constant SFDR performance across input frequencies.

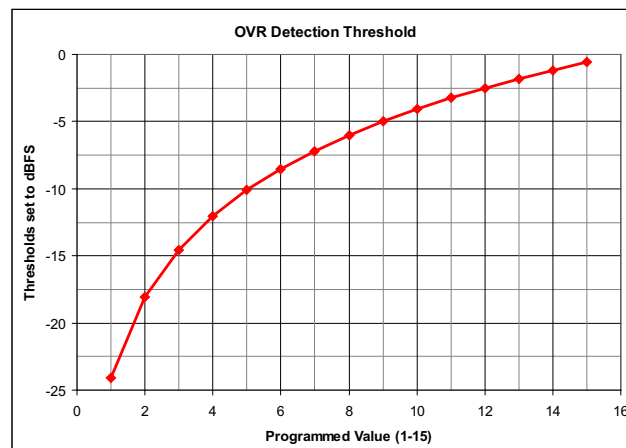
The common-mode voltage of the signal inputs is internally biased to 1.9V using 500Ω resistors which allows for AC coupling of the input drive network. Each input pin (INP, INM) must swing symmetrically between $(V_{CM} + 0.25V)$ and $(V_{CM} - 0.25V)$, resulting in a 1.0Vpp (default) differential input swing. The input sampling circuit has a 3dB bandwidth that extends up to 1.2GHz.



OVER-RANGE INDICATION

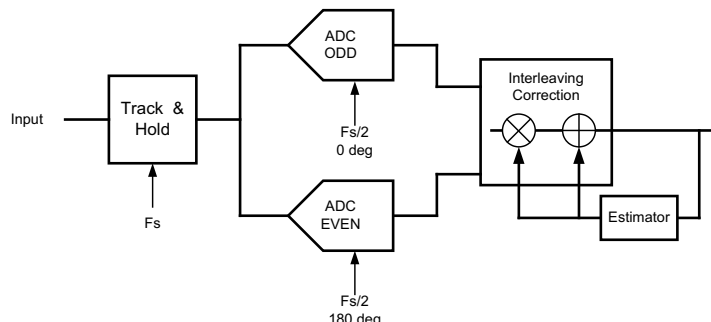
The ADS54T02 provides a fast over-range indication on the OVRA/B pins. The fast OVR is triggered if the input voltage exceeds the programmable overrange threshold and it gets presented after just 12 clock cycles enabling a quicker reaction to an overrange event. The OVR threshold can be configured using SPI register writes.

The input voltage level at which the overload is detected is referred to as the threshold and is programmable using the Over-range threshold bits. The threshold at which fast OVR is triggered is $(\text{full-scale} \times [\text{the decimal value of the FAST OVR THRESH bits}] / 16)$. After reset, the default value of the over-range threshold is set to 15 (decimal) which corresponds to a threshold of 0.56dB below full scale ($20 \times \log(15/16)$).



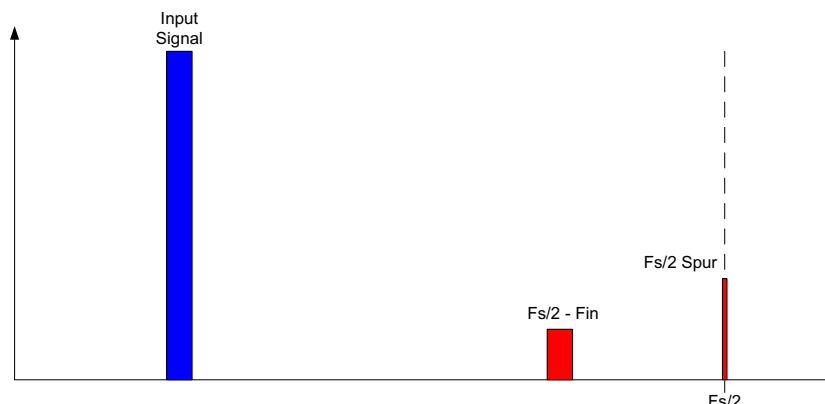
INTERLEAVING CORRECTION

Each of the two data converter channels consists of two interleaved ADCs each operating at half of the ADC sampling rate but 180° out of phase from each other. The front end track and hold circuitry is operating at the full ADC sampling rate which minimizes the timing mismatch between the two interleaved ADCs. In addition the ADS54T02 is equipped with internal interleaving correction logic that can be enabled via SPI register write.



The interleaving operation creates 2 distinct and interleaving products:

- $F_s/2 - F_{in}$: this spur is created by gain timing mismatch between the ADCs. Since internally the front end track and hold is operated at the full sampling rate, this component is greatly improved and mostly dependent on gain mismatch.
- $F_s/2$ Spur: due to offset mismatch between ADCs



The auto correction loop can be enabled via SPI register write in address 0x01. By default it is disabled for lowest possible power consumption. The default settings for the auto correction function should work for most applications. However please contact Texas Instruments if further fine tuning of the algorithm is required.

The auto correction function yields best performance for input frequencies below 250MHz. For input frequencies greater than 250MHz it is recommended to disable the auto gain correction loop.

RECEIVE MODE: DECIMATION FILTER

Each channel has a digital filter in the data path as shown in Figure 36. The filter can be programmed as a low-pass or a high-pass filter and the normalized frequency response of both filters is shown in Figure 37.

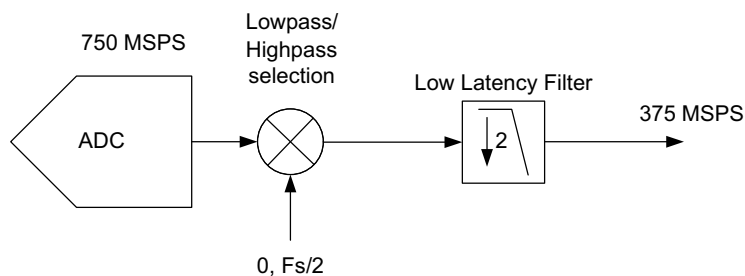


Figure 36.

The decimation filter response has a 0.1dB pass band ripple with approximately 41% pass-band bandwidth. The stop-band attenuation is approximately 40dB.

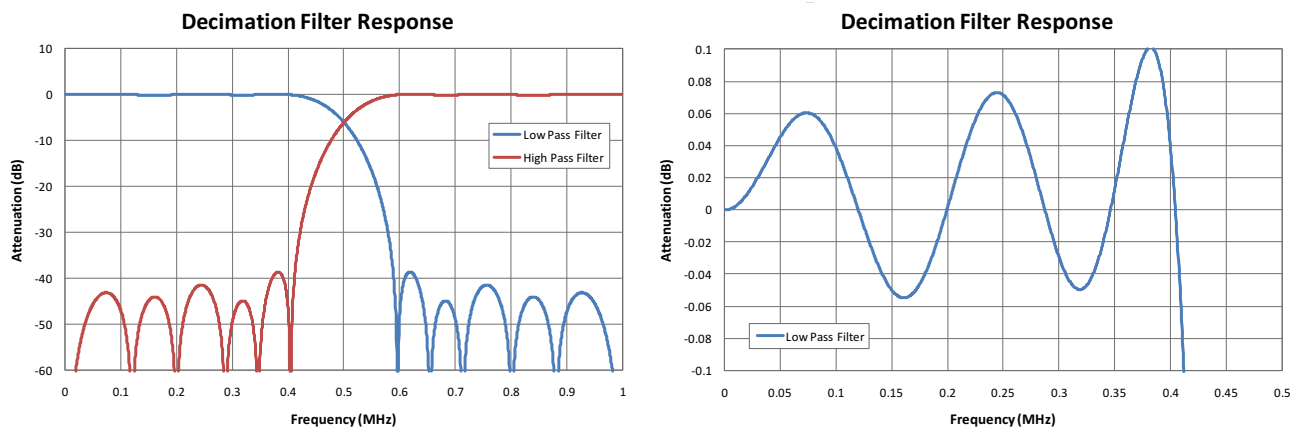


Figure 37.

FEEDBACK MODE: BURST MODE

In burst mode the output data is alternated between a high resolution 12bit output of 2^N samples and a low resolution 9 or 11bit output of 2^{N+3} samples. Burst mode is enabled through SPI register write and there are two basic operating modes available – a manual trigger mode where the high resolution output is initiated through external trigger and an auto trigger mode where the internal logic transitions to high resolution output immediately after transmitting the last low resolution sample. Upon enabling burst mode through a SPI register write, the ADS54T02 transmits 2^{13} low resolution samples and the trigger command is locked out until completion.

The parameter N can be changed via SPI at any time. It will go in effect with the next output cycle starting with transmission of low resolution samples. The default value for N after reset is N=10.

| N limit | 10 (minimum) | 25 (maximum) |
|---|--------------|--------------|
| Number of low resolution samples per cycle (2^{N+3}) | 8,192 | 268,435,456 |
| Number of high resolution samples per cycle (2^N) | 1,024 | 33,554,432 |
| Total amount of samples per cycle | 9,216 | 301,989,888 |
| Maximum number of high resolution (12-bit) samples per 1 second | 83.3M | 83.3M |

Manual Trigger Mode

The control of the high resolution output is shown below along with the two output flags (TRDY and HRES).

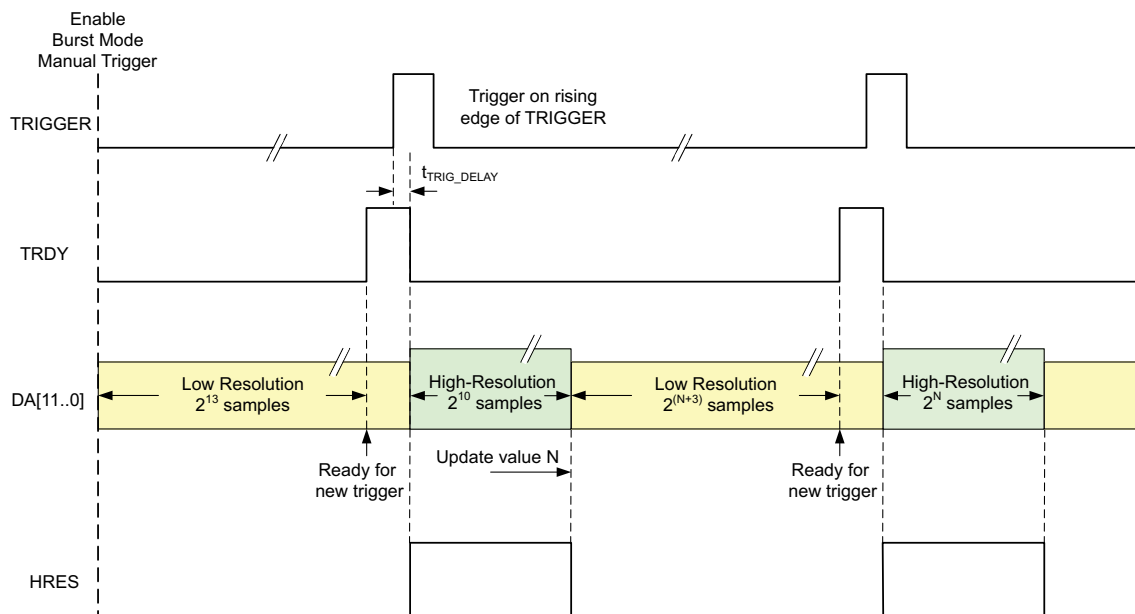


Figure 38. Triggering High Resolution Mode and Lockout Time

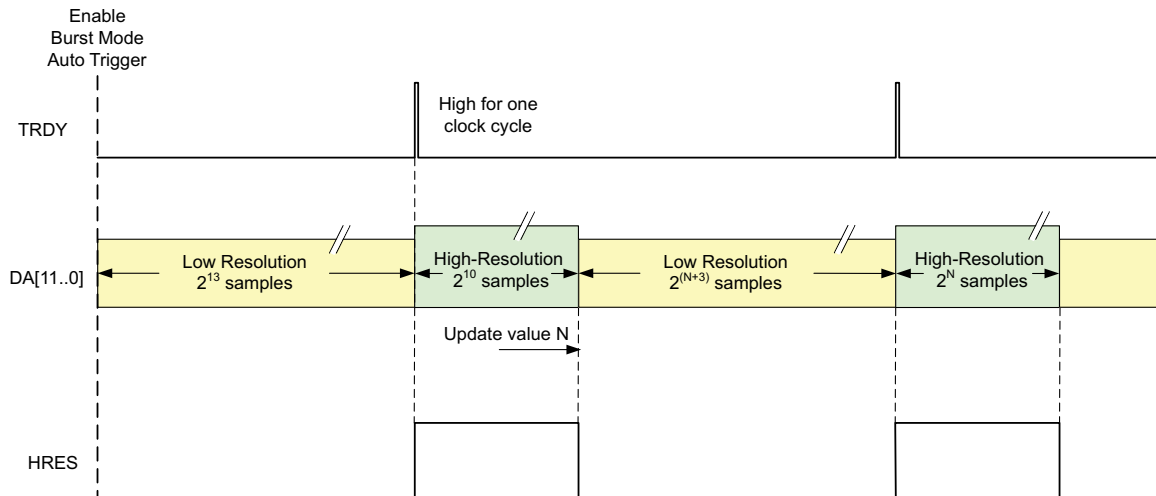
After enabling burst mode, the output data DA[11..0] and DB[11..0] are forced to low resolution mode for 213 samples. During that period any trigger signal is ignored. The completion of the low resolution sample cycle is signaled by a logic high on the TRDY output pins indicating that a high resolution (12-bit) data output burst can be triggered by a low to high transition on the TRIGGER input. The ADC monitors the TRIGGER input at each rising edge of the input clock.

The high resolution output data starts with a delay of $t_{TRIG_DELAY} = 1\text{-}2 \text{ DA/BCLK}$ clock cycles and is indicated through the HRES data flag which stays high for all 2^N high resolution samples. At completion the register value for N is verified and transmission of $2^{(N+3)}$ low resolution data immediately follows. Once the last low resolution sample is output on the output data bus, the flag TRDY is asserted high again indicating the end of the lockout period and the next 2^N high resolution samples can be triggered again.

Auto Trigger Mode

This mode is enabled by setting the auto trigger bit via SPI register write and the DA/DB data outputs start in low resolution for 2^{13} samples. Immediately following completion of transmission of the last low resolution sample, the outputs automatically start transmitting 2^{10} high resolution samples without the need for external trigger ensuring maximum efficiency. Any input signal on the TRIGGER pins is ignored and the TRDY flag will go high only for one clock cycle with the start of the high resolution data.

The output flag HRES is aligned with the 2^N high resolution output samples and the parameter N can be changed until the next output cycle starts again with low resolution output data.



High Resolution Output Data

After trigger, the data outputs DA[11..0]/DB[11..0] are 12-bit resolution for 2^N samples, where N is a programmable register with a range $10 \leq N \leq 25$ (corresponding to 1024 to 33554432 samples).

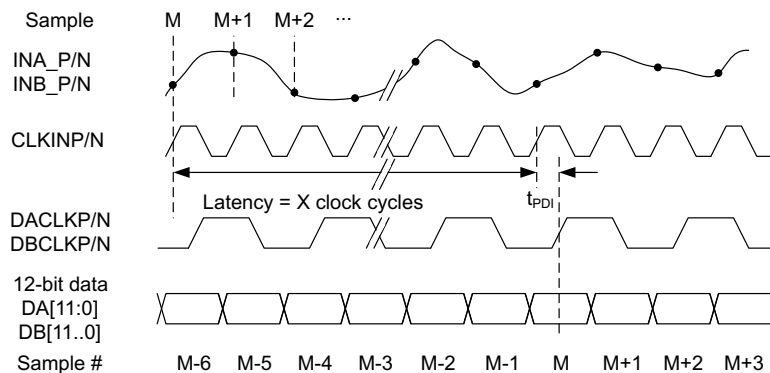


Figure 39. High Resolution Data Output Timing

After the high resolution data, the data output returns to low resolution mode, the logic level of the HRES flag returns low and the trigger is locked out for $2^{(N+3)}$ samples. N is the sample integer resulting in a maximum output duty cycle of 1/9. During the trigger lockout time, a low to high transition on TRIGGERP/N will be ignored. After the 2^{N+3} low resolution samples, the TRIGGERP/N is re-enabled for the next valid data burst.

Low Resolution Output Data

There are two different options for the low resolution output data and the selection is made through SPI register control. The data can either be output at full speed (ADC sampling rate) with the output resolution limited to 9bit (9 MSBs). Alternatively the output resolution can be selected to 11bit (11 MSBs) but at a reduced effective data rate where every 4th sample gets repeated four times.

Full Speed – 9bit

The output data rate and timing is exactly the same as the high resolution data – only the output resolution is limited to the 9 MSBs.

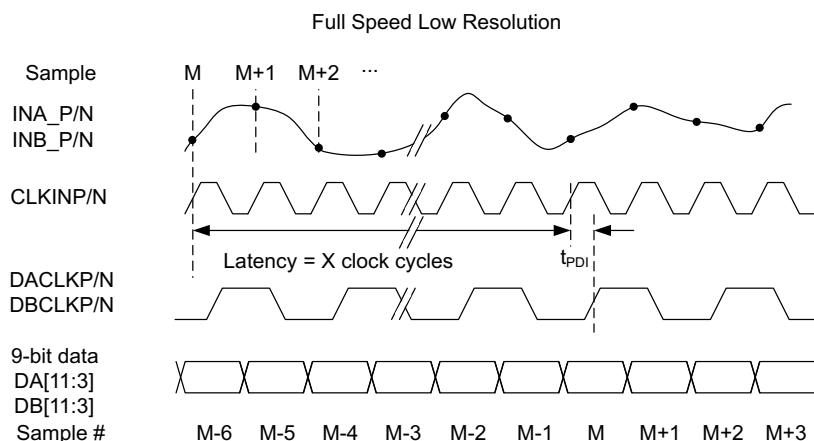


Figure 40. Full Rate Low Resolution Output Data Timing

Decimated Low Resolution Output Data

In decimated low resolution mode the output data is limited to 11-bits and every sample is repeated four times so the effective data rate is 1/4 of ADC sampling rate. The latency of the ADC sample to output sample is exactly the same as for high resolution data – there is no uncertainty in which conversion sample results in the valid output data. This is because the output continues to run at the ADC sample rate – only the resolution is changed and three out of four samples are deleted.

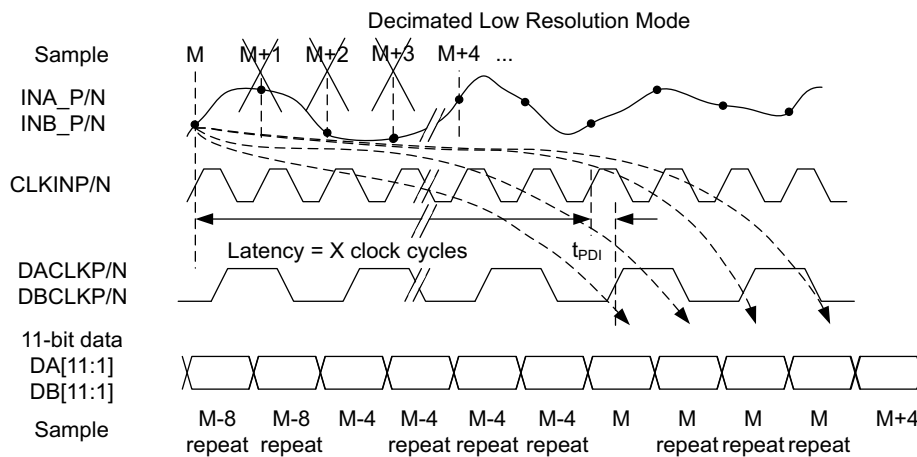
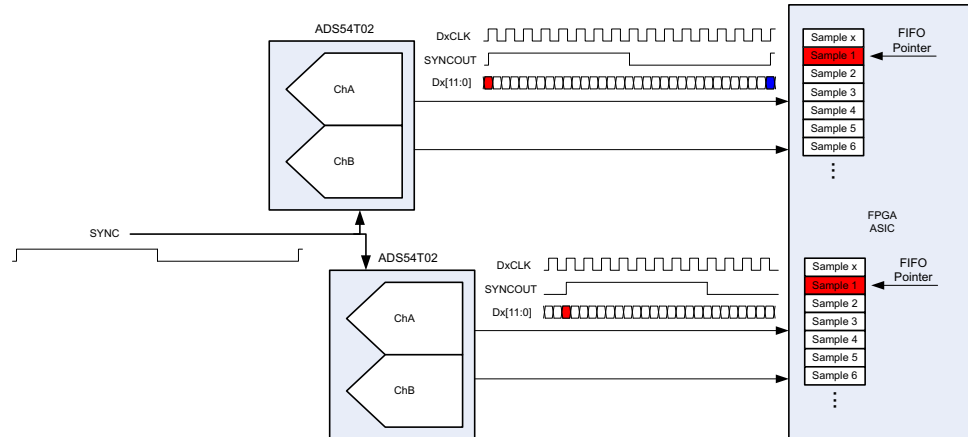


Figure 41. Decimated Low Resolution Output Data Timing Diagram

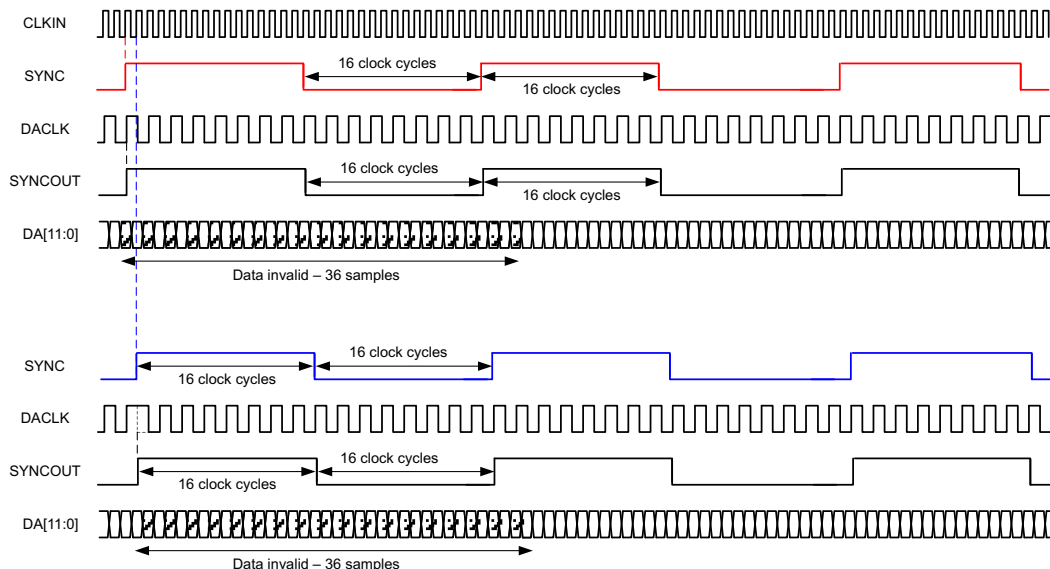
MULTI DEVICE SYNCHRONIZATION

The ADS54T02 simplifies the synchronization of data from multiple ADCs in one common receiver. Upon receiving the initial SYNC input signal, the ADS54T02 resets all the internal clocks and digital logic while also starting a SYNCOUT signal which operates on a 5bit counter (32 clock cycles). Therefore by providing a common SYNC signal to multiple ADCs their output data can be synchronized as the SYNCOUT signal marks a specific sample with the same latency in all ADCs. The SYNCOUT signal then can be used in the receiving device to synchronize the FIFO pointers across the different input data streams. Thus the output data of multiple ADCs can be aligned properly even if there are different trace lengths between the different ADCs.



The SYNC input signal should be a periodic signal repeating every 32 CLKIN clock cycles. It gets registered on the rising edge of the ADC input clock (CLKIN). Upon registering the initial rising edge of the SYNC signal, the internal clocks and logic get reset which results in invalid output data for 36 samples (1 complete sync cycle and 4 additional samples). The SYNCOUT signal starts with the next output clock (DACLK) rising edge and operates on a 5-bit counter independent from the SYNC signal frequency and duty cycle.

Since the ADS54T02 output interface operates with a DDR clock, the synchronization can happen on the rising edge or falling edge sample. Synchronization on the falling edge sample will result in a half cycle clock stretch of DA/BCLK. For convenience the SYNCOUT signal is available on the ChA/B output LVDS bus. When using decimation the SYNCOUT signal still operates on 32 clock cycles of CLKIN but since the output data is decimated by 2, only the first 18 samples should be discarded.



PROGRAMMING INTERFACE

The serial interface (SIF) included in the ADS54T02 is a simple 3 or 4 pin interface. In normal mode, 3 pins are used to communicate with the device. There is an enable (SDENB), a clock (SCLK) and a bi-directional IO port (SDIO). If the user would like to use the 4 pin interface one write must be implemented in the 3 pin mode to enable 4 pin communications. In this mode, the SDO pin becomes the dedicated output. The serial interface has an 8-bit address word and a 16-bit data word. The first rising edge of SCLK after SDENB goes low will latch the read/write bit. If a high is registered then a read is requested, if it is low then a write is requested. SDENB must be brought high again before another transfer can be requested. The signal diagram is shown below:

Register Initialization

After power up, the internal registers must be initialized to the default values. This initialization can be accomplished in one of two ways:

1. Either through hardware reset by applying a low pulse on SRESET pin
2. By applying a software reset. When using the serial interface, a reset can be performed by addressing register x2C. This setting initializes the internal registers to the default values and then self-resets the RESET register to 0. In this case the SRESET pin can be kept high.

Serial Register Write

The internal register of the ADS54T02 can be programmed following these steps:

1. Drive SDENB pin low
2. Set the R/W bit to '0' (bit A7 of the 8 bit address)
3. Initiate a serial interface cycle specifying the address of the register (A6 to A0) whose content has to be written
4. Write 16bit data which is latched on the rising edge of SCLK

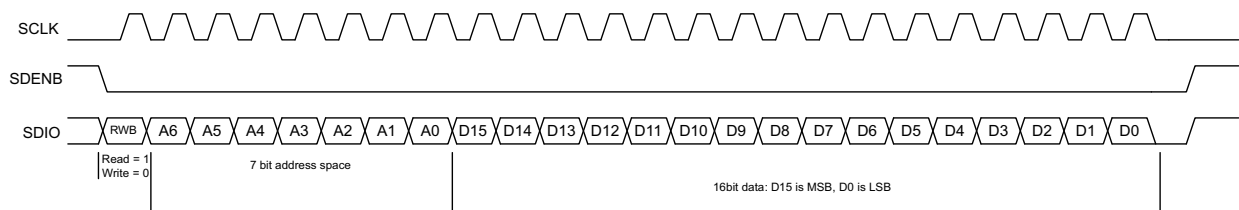


Figure 42. Serial Register Write Timing Diagram

| PARAMETER | | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|---------------------|--|-----|--------------------|-----|------|
| f _{SCLK} | SCLK frequency (equal to 1/t _{SCLK}) | >DC | | 20 | MHz |
| t _{SLOADS} | SDENB to SCLK setup time | 25 | | | ns |
| t _{SLOADH} | SCLK to SDENB hold time | 25 | | | ns |
| t _{DSU} | SDIO setup time | 25 | | | ns |
| t _{DH} | SDIO hold time | 25 | | | ns |

(1) Typical values at +25°C; minimum and maximum values across the full temperature range: TMIN = –40°C to TMAX = +85°C, AVDD3V = 3.3V, AVDD, DRVDD = 1.9V, unless otherwise noted.

Serial Register Readout

The device includes a mode where the contents of the internal registers can be read back using the SDO/SDIO pins. This read-back mode may be useful as a diagnostic check to verify the serial interface communication between the external controller and the ADC.

1. Drive SDENB pin low
2. Set the RW bit (A7) to '1'. This setting disables any further writes to the registers
3. Initiate a serial interface cycle specifying the address of the register (A6 to A0) whose content has to be read.
4. The device outputs the contents (D15 to D0) of the selected register on the SDO/SDIO pin
5. The external controller can latch the contents at the SCLK rising edge.
6. To enable register writes, reset the RW register bit to '0'.

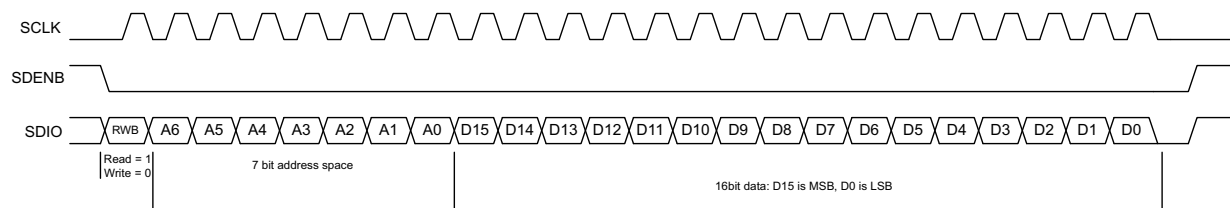


Figure 43. Serial Register Read Timing Diagram

SERIAL REGISTER MAP⁽²⁾

(2) Multiple functions in a register can be programmed in a single write operation.

| Register Address | Register Data | | | | | | | | | | | | | | | |
|------------------|-----------------------|---------------------|--------------|--------------------|-----|---------------------------|--------------------|-------------|----|----------|------------|----------|-------------|--------------|----------|---------|
| A7–A0 IN HEX | D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| 0 | 3/4 Wire SPI | DecFil/ Burst | 0 | ChA High/ Low Pass | 0 | 0 | ChB High/ Low Pass | 0 | 0 | 0 | Burst rate | 0 | 0 | Auto Trigger | 0 | 0 |
| 1 | ChA Corr EN | 0 | 0 | 0 | 0 | 0 | ChB Corr EN | 0 | 0 | 0 | 0 | 0 | Data Format | 0 | Hp Mode1 | 0 |
| 2 | 0 | 1 | 0 | 0 | 0 | Over-range threshold | | | | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 3 | 0 | Start Auto Corr ChA | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 0 |
| E | Sync Select | | | | | | | | | | | | | | | |
| F | Sync Select | | | | 0 | 0 | 0 | 0 | 0 | VREF Set | | | 0 | 0 | 0 | 0 |
| 1A | 0 | Start Auto Corr ChB | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 0 |
| 2B | 0 | 0 | 0 | 0 | 0 | 0 | 0 | Temp Sensor | | | | | | | | |
| 2C | Reset | | | | | | | | | | | | | | | |
| 34 | 0 | 0 | Burst Mode N | | | | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 37 | Sleep Modes | | | | | | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |
| 38 | HP Mode2 | | | | | | | | | BIAS EN | SYNC EN | TRIGEN | 0 | 0 | 0 | 0 |
| 3A | LVDS Current Strength | | | LVDS SW | | Internal LVDS Termination | | 0 | 0 | 0 | 0 | DACLK EN | DBCLK EN | 0 | OVRA EN | OVRB EN |
| 66 | LVDS Output Bus A EN | | | | | | | | | | | | | | | |
| 67 | LVDS Output Bus B EN | | | | | | | | | | | | | | | |

DESCRIPTION OF SERIAL INTERFACE REGISTERS

| Register Address | Register Data | | | | | | | | | | | | | | | |
|------------------|---------------|----------------|-----|-------------------|-----|-----|-------------------|----|----|----|------------|----|----|--------------|----|----|
| A7-A0 in hex | D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| 0 | 3/4 Wire SPI | Dec Fil/ Burst | 0 | ChA High/Low Pass | 0 | 0 | ChB High/Low Pass | 0 | 0 | 0 | Burst rate | 0 | 0 | Auto Trigger | 0 | 0 |

- D15 3/4 Wire SPI** Enables 4-bit serial interface when set
Default 0
- 0 3 wire SPI is used with SDIO pin operating as bi-directional I/O port
- 1 4 wire SPI is used with SDIO pin operating as data input and SDO pin as data output port.
- D14 DecFil/ Burst** 2x decimation filter (Receive Mode) is enabled when bit is set
Default 0
- 0 Burst mode enable
- 1 2x decimation filter enabled
- D12 ChA High/Low Pass** (Decimation filter must be enabled first: set bit D14)
Default 0
- 0 Low Pass
- 1 High Pass
- D9 ChB High/Low Pass** (Decimation filter must be enabled first: set bit D14)
Default 0
- 0 Low Pass
- 1 High Pass
- D5 Burst Rate** Low resolution output data rate in burst mode
Default 0
- 0 Low resolution (9bit) full output rate
- 1 Decimated low resolution output (4x decimation, 11bit resolution)
- D2 Auto Trigger** Enables auto trigger mode in burst mode without the need to control the trigger pin.
Default 0
- 0 Manual trigger mode using the external trigger input pin
- 1 Auto trigger mode enabled

| Register Address | Register Data | | | | | | | | | | | | | | | |
|------------------|-------------------|-----|-----|-----|-----|-----|-------------------|----|----|----|----|----|----------------|----|-------------|----|
| A7-A0 in hex | D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| 1 | ChA Corr EN | 1 | 0 | 0 | 0 | 0 | ChB Corr EN | 0 | 0 | 0 | 0 | 0 | Data Format | 0 | HP Mode1 | 0 |

D15 ChA Corr EN (should be enabled for maximum performance)

Default 0

0 Auto correction disabled

1 Auto correction enabled

D9 ChB Corr EN (should be enabled for maximum performance)

Default 0

0 Auto correction disabled

1 Auto correction enabled

D3 Data Format

Default 0

0 Two's complement

1 Offset Binary

D1 HP Mode 1

Default 0

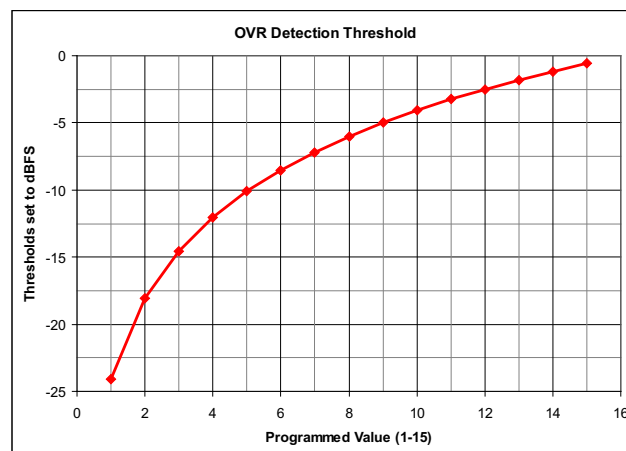
1 Must be set to 1 for optimum performance

| Register Address | Register Data | | | | | | | | | | | | | | | |
|------------------|---------------|-----|-----|-----|-----|----------------------|----|----|----|----|----|----|----|----|----|----|
| A7-A0 in hex | D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| 2 | 0 | 1 | 0 | 0 | 0 | Over-range threshold | | | | | 0 | 0 | 0 | 0 | 0 | 0 |

D14 Read back 1.

D10-D7 Over-range threshold The over-range detection is triggered 12 output clock cycles after the overload condition occurs. The threshold at which the OVR is triggered = $1.0V \times [\text{decimal value of } \langle \text{Over-range threshold} \rangle] / 16$. After power up or reset, the default value is 15 (decimal) which corresponds to a OVR threshold of 0.56dB below fullscale ($20 \times \log(15/16)$). This OVR threshold is applicable to both channels.

Default 1111



| Register Address | Register Data | | | | | | | | | | | | | | | |
|------------------|---------------|---------------------|-----|-----|-----|-----|----|----|----|----|----|----|----|----|----|----|
| A7-A0 in hex | D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| 3 | 0 | Start Auto Corr ChA | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 0 |

D14 Start Auto Corr ChA Starts DC offset and Gain correction loop for ChA
Default 1

0 Starts the DC offset and Gain correction loops

1 Clears DC offset correction value to 0 and Gain correction value to 1

D11, 9, 8, 4, 3 Must be set to 1 for maximum performance
Default 1

| Register Address | Register Data | | | | | | | | | | | | | | | |
|------------------|---------------|-----|-----|-----|-----|-----|----|----|----|----|----|----|----|----|----|----|
| A7-A0 in hex | D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| E | Sync Select | | | | | | | | | | | | | | | |

D15-D2 **Sync Select** Sync selection for the clock generator block (also need to see address 0x0F)
 Default 1010 1010 1010 10
 0000 0000 0000 00 Sync is disabled
 0101 0101 0101 01 Sync is set to one shot (one time synchronization only)
 1010 1010 1010 10 Sync is derived from SYNC input pins
 1111 1111 1111 11 not supported

| Register Address | Register Data | | | | | | | | | | | | | | | |
|------------------|---------------|-----|-----|-----|-----|-----|----|----|----|----------|----|----|----|----|----|----|
| A7-A0 in hex | D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| F | Sync Select | | | | 0 | 0 | 0 | 0 | 0 | VREF Sel | | | 0 | 0 | 0 | 0 |

D15-D12 **Sync Select** Sync selection for the clock generator block
 Default 1010
 0000 Sync is disabled
 0101 Sync is set to one shot (one time synchronization only)
 1010 Sync is derived from SYNC input pins
 1111 not supported
D6-D4 **VREF SEL** Internal voltage reference selection
 Default 000
 000 1.0V
 001 1.25V
 010 0.9V
 011 0.8V
 100 1.15V
 Others external reference

| Register Address | Register Data | | | | | | | | | | | | | | | |
|------------------|---------------|---------------------|-----|-----|-----|-----|----|----|----|----|----|----|----|----|----|----|
| A7-A0 in hex | D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| 1A | 0 | Start Auto Corr ChB | 0 | 0 | 1 | 0 | 1 | 1 | 0 | 0 | 0 | 1 | 1 | 0 | 0 | 0 |

D14 **Start Auto Corr ChB** Starts DC offset and Gain correction loop for ChB
 Default 1
 0 Starts the DC offset and Gain correction loops
 1 Clears DC offset correction value to 0 and Gain correction value to 1
D11, 9, 8, 4, 3 Must be set to 1 for maximum performance
 Default 1

| Register Address | Register Data | | | | | | | | | | | | | | | |
|------------------|---------------|-----|-----|-----|-----|-----|----|-------------|----|----|----|----|----|----|----|----|
| A7-A0 in hex | D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| 2B | 0 | 0 | 0 | 0 | 0 | 0 | 0 | Temp Sensor | | | | | | | | |

D8-D0 **Temp Sensor** Internal temperature sensor value – read only

| Register Address | Register Data | | | | | | | | | | | | | | | |
|------------------|---------------|-----|-----|-----|-----|-----|----|----|----|----|----|----|----|----|----|----|
| A7-A0 in hex | D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| 2C | Reset | | | | | | | | | | | | | | | |

D15-D0 **Reset** This is a software reset to reset all SPI registers to their default value. Self Default 0000 clears to 0.

1101001011110000 Perform software reset

| Register Address | Register Data | | | | | | | | | | | | | | | |
|------------------|---------------|-----|--------------|-----|-----|-----|----|----|----|----|----|----|----|----|----|----|
| A7-A0 in hex | D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| 34 | 0 | 0 | Burst Mode N | | | | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |

D13-D10 **Burst Mode N** This is the parameter that sets the amount of high resolution Default 0000 samples in burst mode

0000 N = 10

0001 N = 11

... ...

1111 N = 25

| Register Address | Register Data | | | | | | | | | | | | | | | |
|------------------|---------------|-----|-----|-----|-----|-----|----|----|----|----|----|----|----|----|----|----|
| A7-A0 in hex | D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| 37 | Sleep Modes | | | | | | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 | 0 |

D15-D14 **Sleep Modes** Sleep mode selection which is controlled by the ENABLE pin. Sleep modes are active when Default 00 ENABLE pin goes low.

000000 Complete shut down Wake up time 2.5 ms

100000 Stand-by mode Wake up time 100 μ s

110000 Deep sleep mode Wake up time 20 μ s

110101 Light sleep mode Wake up time 2 μ s

| Register Address | Register Data | | | | | | | | | | | | | | | |
|------------------|---------------|-----|-----|-----|-----|-----|----|----|----|---------|---------|---------|----|----|----|----|
| | D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| 38 | HP Mode 2 | | | | | | | | | Bias EN | SYNC EN | TRIG EN | 0 | 0 | 0 | 0 |

D15-D7 HP Mode 2

Default 11111111

1 Set to 1 for normal operation

D6 BIAS EN

Default 1

Enables internal fuse bias voltages – can be disabled after power up to save power.

0 Internal bias powered down

1 Internal bias enabled

D5 SYNC EN

Default 1

Enables the SYNC input buffer.

0 SYNC input buffer disabled

1 SYNC input bffer enabled

D4 TRIG EN

Default 1

Enables the TRIGGER input buffer.

0 TRIGGER input buffer disabled

1 TRIGGER input bffer enabled

| Register Address | Register Data | | | | | | | | | | | | | | | |
|------------------|-----------------------|-----|-----|---------|-----|---------------------------|----|----|----|----|----|----------|----------|----|---------|---------|
| A7-A0 in hex | D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| 3A | LVDS Current Strength | | | LVDS SW | | Internal LVDS Termination | | 0 | 0 | 0 | 0 | DACLK EN | DBCLK EN | 0 | OVRA EN | OVRB EN |

| | | | |
|---------|----------------------------------|--|---------|
| D15-D13 | LVDS Current Strength | LVDS output current strength. | |
| | Default 000 | | |
| 000 | 2 mA | 100 | 3 mA |
| 001 | 2.25 mA | 101 | 3.25 mA |
| 010 | 2.5 mA | 110 | 3.5 mA |
| 011 | 2.75 mA | 111 | 3.75 mA |
| D12-D11 | LVDS SW | LVDS driver internal switch setting – correct range must be set for setting in D15-D13 | |
| | Default 01 | | |
| 01 | 2 mA to 2.75 mA | | |
| 11 | 3mA to 3.75mA | | |
| D10-D9 | Internal LVDS Termination | Internal termination | |
| | Default 00 | | |
| 00 | 2 kΩ | | |
| 01 | 200 Ω | | |
| 10 | 200 Ω | | |
| 11 | 100 Ω | | |
| D4 | DACLK EN | Enable DACLK output buffer | |
| | Default 1 | | |
| 0 | DACLK output buffer powered down | | |
| 1 | DACLK output buffer enabled | | |
| D3 | DBCLK EN | Enable DBCLK output buffer | |
| | Default 1 | | |
| 0 | DBCLK output buffer powered down | | |
| 1 | DBCLK output buffer enabled | | |
| D1 | OVRA EN | Enable OVRA output buffer | |
| | Default 1 | | |
| 0 | OVRA output buffer powered down | | |
| 1 | OVRA output buffer enabled | | |
| D0 | OVRB EN | Enable OVRB output buffer | |
| | Default 1 | | |
| 0 | OVRB output buffer powered down | | |
| 1 | OVRB output buffer enabled | | |

| Register Address | Register Data | | | | | | | | | | | | | | | |
|------------------|----------------------|-----|-----|-----|-----|-----|----|----|----|----|----|----|----|----|----|----|
| A7-A0 in hex | D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| 66 | LVDS Output Bus A EN | | | | | | | | | | | | | | | |

D15-D10 **LVDS Output Bus A EN** Individual LVDS output pin power down for channel A
Default FFFF
0 Output is powered down
1 Output is enabled

D15 corresponds to TRDYP/N (pins N7, P7)
D14 corresponds to HRESP/N (pins N6, P6)
D13 SYNCOUTP/N (pins N5, P5)
D12 Pins N4, P4 (no connect pins) which are not used and should be powered down for power savings
D11-D0 corresponds to DA11-D0

| Register Address | Register Data | | | | | | | | | | | | | | | |
|------------------|----------------------|-----|-----|-----|-----|-----|----|----|----|----|----|----|----|----|----|----|
| A7-A0 in hex | D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
| 67 | LVDS Output Bus B EN | | | | | | | | | | | | | | | |

D15-D10 **LVDS Output Bus B EN** Individual LVDS output pin power down for channel B
Default FFFF
0 Output is powered down
1 Output is enabled

D15 corresponds to TRDYP/N (pins G3, G4)
D14 corresponds to HRESP/N (pins F3, F4)
D13 SYNCOUTP/N (pins F1, F2)
D12 Pins E3, E4 (no connect pins) which are not used and should be powered down for power savings
D11-D0 corresponds to DB11-DB0

REVISION HISTORY

| Changes from Original (January 2013) to Revision A | Page |
|---|------|
| • Changed D15-10 in register 66 From: Individual LVDS output pin power down for channel B To: Individual LVDS output pin power down for channel A | 39 |
| • Changed D15 in register 66 From: corresponds to TRDYP/N (pins G3, G4) To: corresponds to TRDYP/N (pins N7, P7) | 39 |
| • Changed D14 in register 66 From: corresponds to HRESP/N (pins F3, F4) To: corresponds to HRESP/N (pins N6, P6) | 39 |
| • Changed D13 in Register 66 From: SYNCOUTP/N (pins F1, F2) To: SYNCOUTP/N (pins N5, P5) | 39 |
| • Changed D12 in Register 66 From: "Pins E3, E4..." To: "Pins N4, P4..." | 39 |
| • Changed D11-D10 - corresponds to DB11-DB0 in Register 66 To: D11-D0 - corresponds to DA11-D0 | 39 |
| • Changed D11-D10 - corresponds to DB11-DB0 in Register 67 To: D11-D0 - corresponds to DB11-DB0 | 39 |

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead/Ball Finish | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|----------------------------|------------------|----------------------|--------------|-------------------------|-------------------------|
| ADS54T02IZAY | ACTIVE | NFBGA | ZAY | 196 | 160 | Green (RoHS & no Sb/Br) | SNAGCU | Level-3-260C-168 HR | -40 to 85 | ADS54T02I | Samples |
| ADS54T02IZAYR | ACTIVE | NFBGA | ZAY | 196 | 1000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-3-260C-168 HR | -40 to 85 | ADS54T02I | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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TAPE AND REEL INFORMATION


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| ADS54T02IZAYR | NFBGA | ZAY | 196 | 1000 | 330.0 | 24.4 | 12.3 | 12.3 | 2.3 | 16.0 | 24.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS

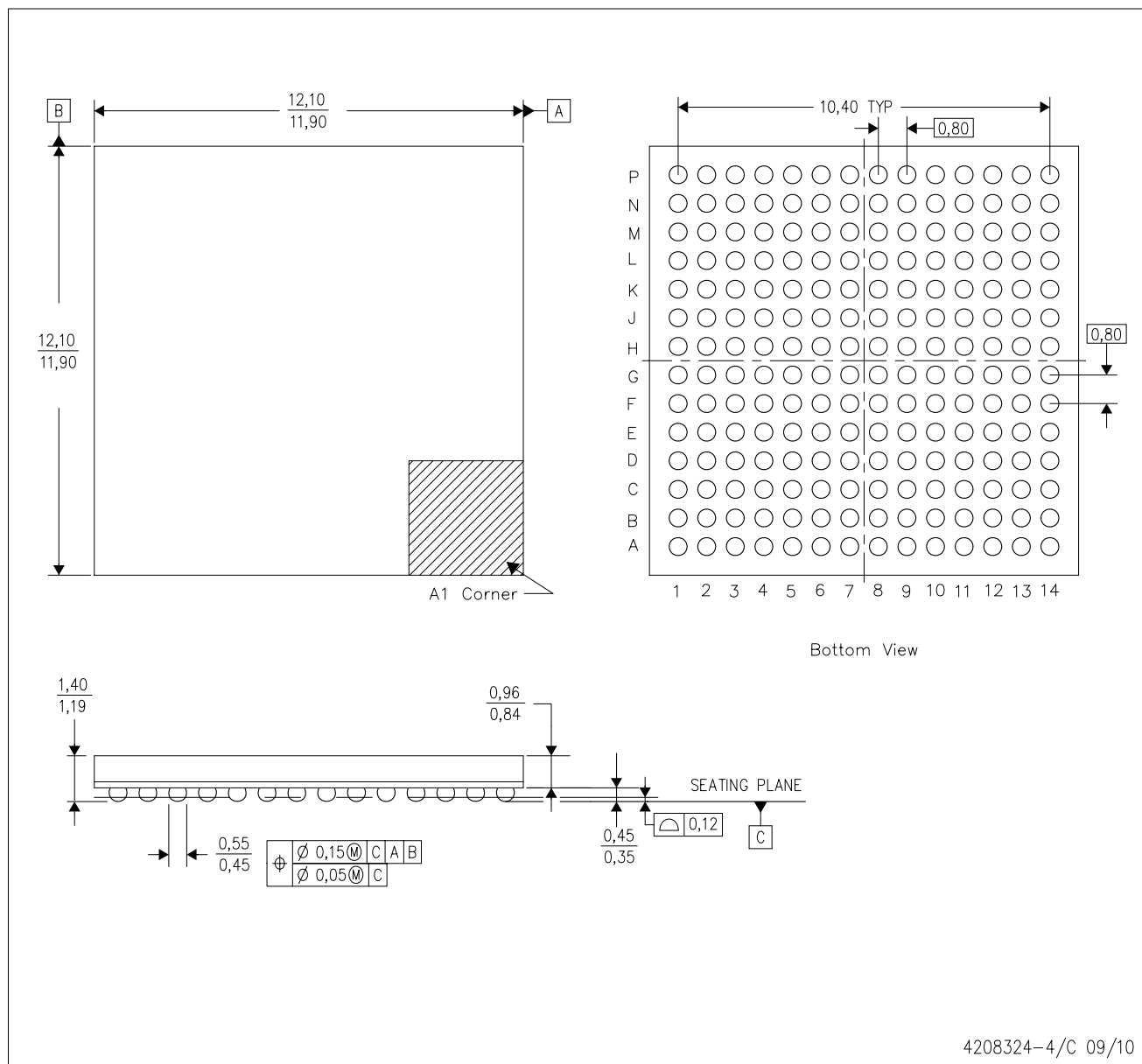


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| ADS54T02IZAYR | NFBGA | ZAY | 196 | 1000 | 336.6 | 336.6 | 31.8 |

ZAY (S-PBGA-N196)

PLASTIC BALL GRID ARRAY



- NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.
C. This is a Pb-free solder ball design.

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